

RF-SAMPLING ADCS FOR NEXT-GENERATION WIRELESS APPLICATIONS

Jorge Lagos, on behalf of the imec ADC team

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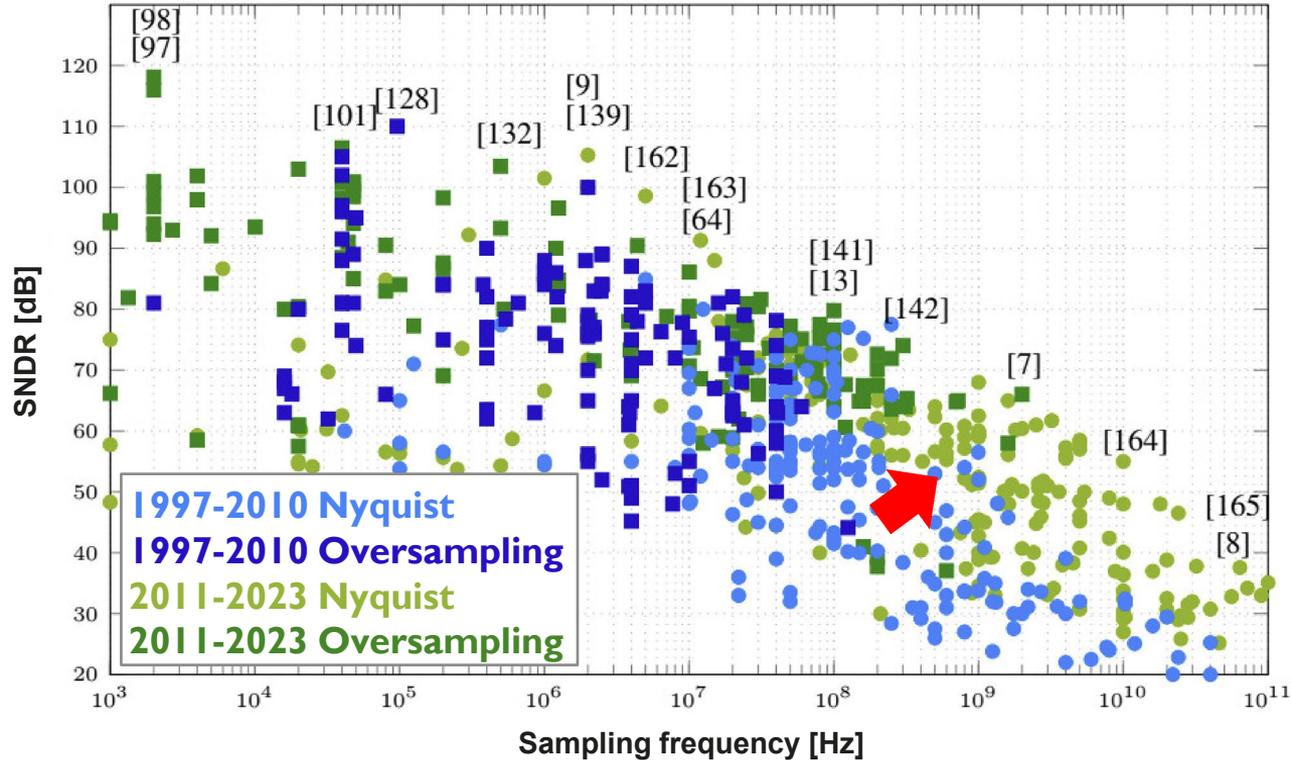
- Motivation
- RF-sampling ADCs: challenges & tradeoffs
- Key enabling technologies for high-performance, power-efficient RF-sampling ADCs
 1. Fast & power-efficient channel
 2. Signal-integrity-preserving hierarchical interleaving
 3. High-linearity, wideband front-end buffer
- Recent experimental results
- Conclusions

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ADCs STATE-OF-THE-ART – RESOLUTION vs. SPEED

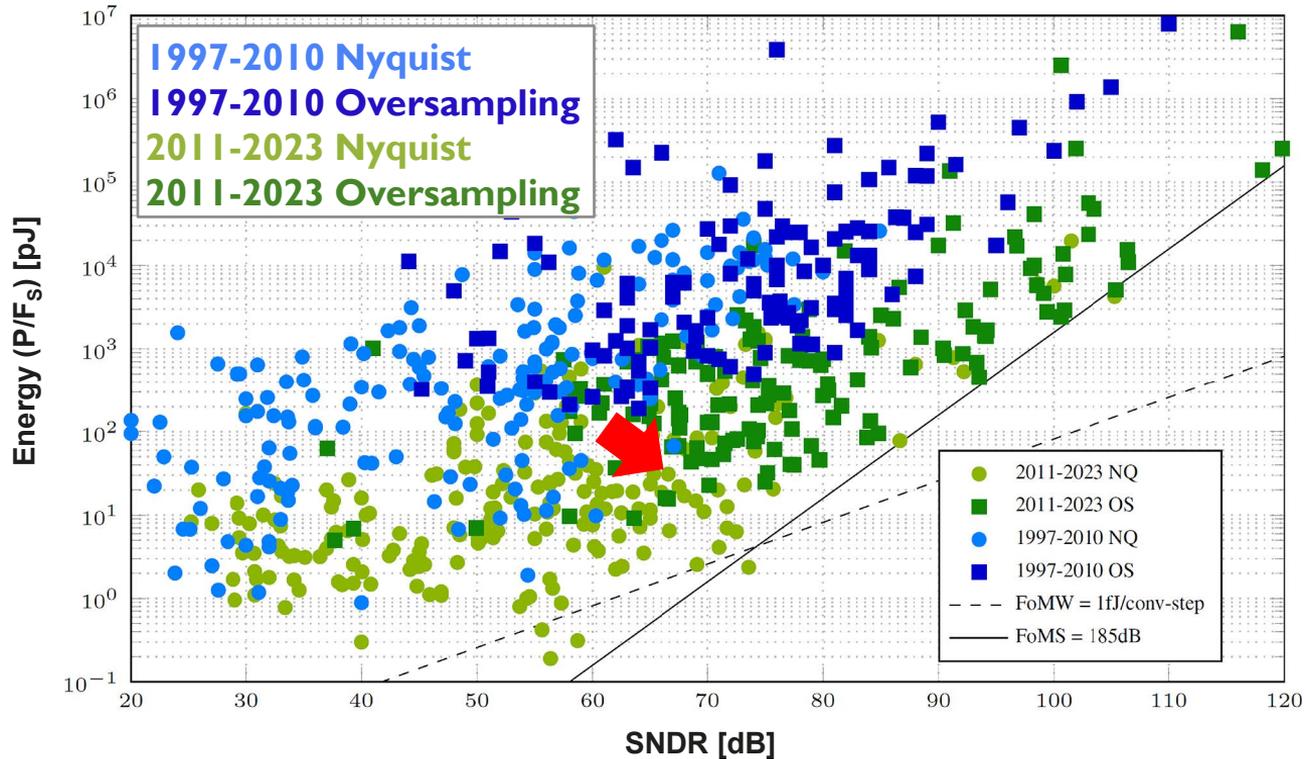
ISSCC/VLSI 1997-2023^{[1][2]}



- Ever-increasing demand for performance

ADCs STATE-OF-THE-ART – ENERGY vs. RESOLUTION

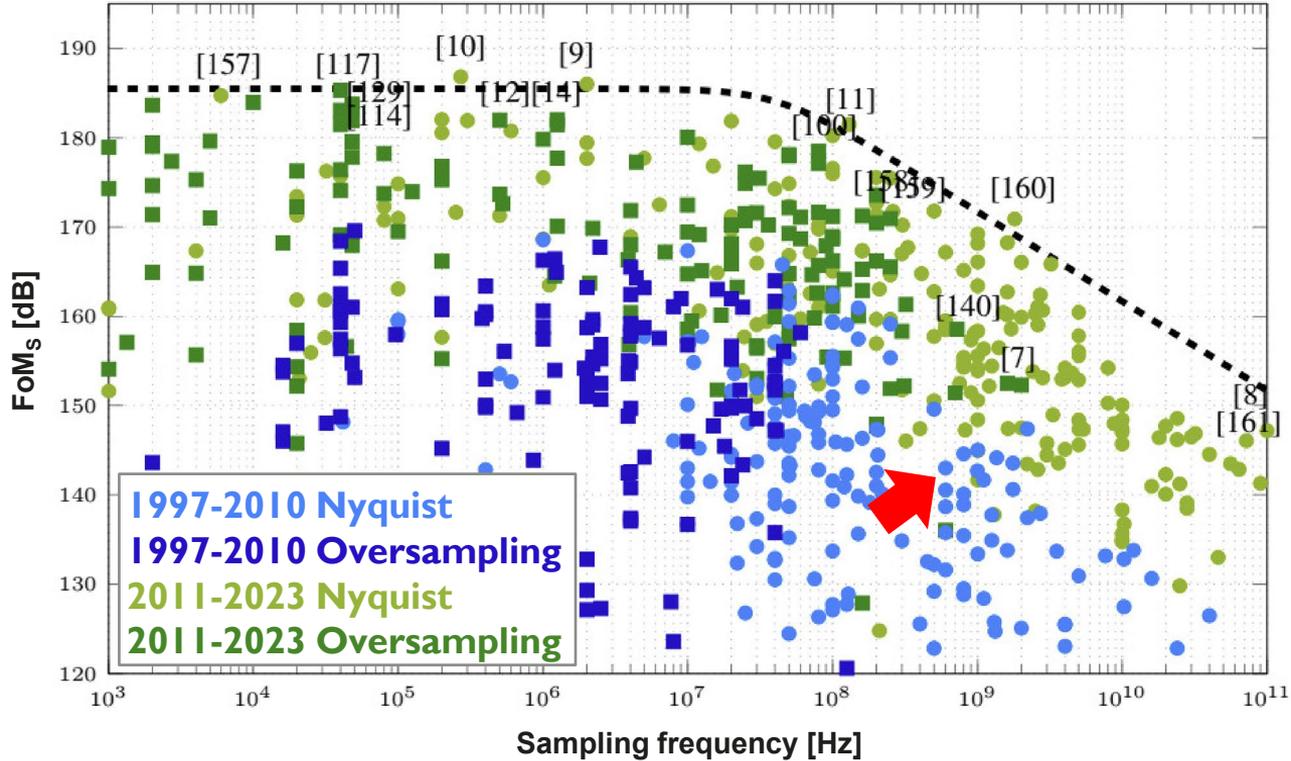
ISSCC/VLSI 1997-2023^{[1][2]}



- Ever-increasing demand for performance & power efficiency!

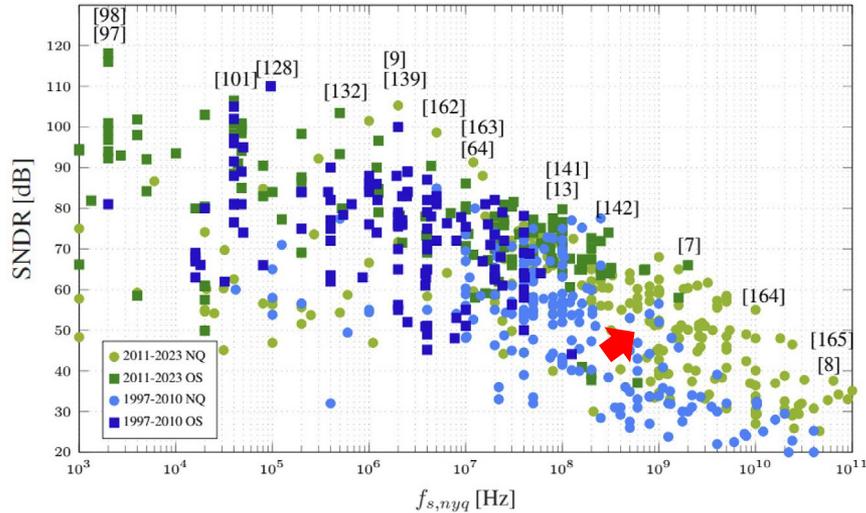
ADCs STATE-OF-THE-ART – POWER EFFICIENCY vs. SPEED

ISSCC/VLSI 1997-2023^{[1][2]}



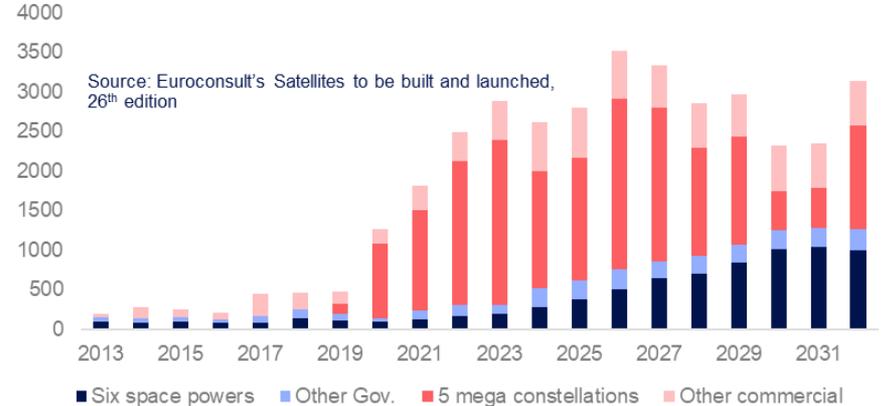
- Ever-increasing demand for performance & power efficiency!

SPACE INDUSTRY IS AMONG CURRENT DRIVING FORCES



A forecast of 28,700 satellites for a total market of \$588 billion over the next 10 years

In # of satellites



■ State-of-the-art RF-sampling ADCs

- Use of **unconventional circuits & deep-nanoscale nodes** to meet performance targets
- The **applicability** of these techniques & nodes to space environments is largely unknown!

■ Goal of this talk:

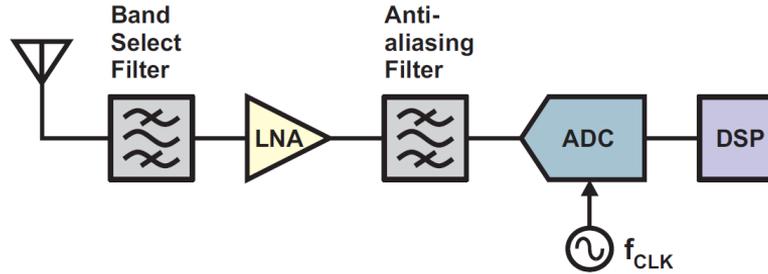
- Give you an idea of the type of **systems you will encounter in future hardening endeavours**

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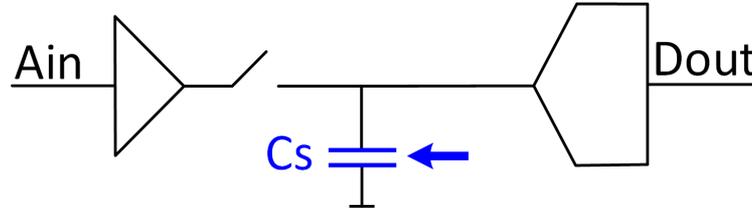
DIRECT RF-SAMPLING RECEIVER

DIRECT DIGITIZATION OF RF SIGNAL



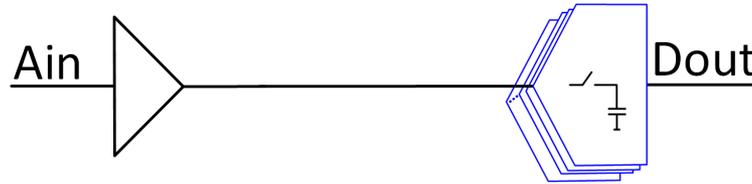
- Several advantages
 - 😊 Reduced analog front-end complexity
 - 😊 Highly reconfigurable → complete flexibility for multi-standard support
 - 😊 Technology-scaling friendly
- But also many challenges ...
 - RF-sampling ADC: must simultaneously achieve wide bandwidth, low noise & high linearity
 - Key tradeoffs
 - Choice of front-end sampling capacitance
 - Choice of interleaving architecture

CHOICE OF FRONT-END SAMPLING CAPACITANCE



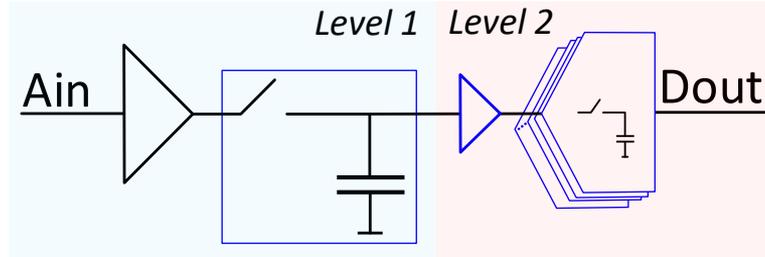
- Direct **noise vs. linearity tradeoff**
 - 😊 Large C_s reduces kT/C noise (fundamental limit) → improved SNR
 - 😞 Large C_s makes wideband linearity extremely challenging
- Front-end buffer & sampler strongly dependent on C_s size
 - 😞 Large C_s exacerbates frequency dependent (dynamic) distortion
 - Very difficult & expensive to calibrate
- Choice of **sampling capacitance must carefully balance these trade-offs**

CHOICE OF ARCHITECTURE: DIRECT INTERLEAVING



- Straightforward parallelization of channels (“sub-ADCs”)
- Fast channel available → reduced # of channels
 - 😊 Less routing parasitics
 - 😊 Reduced interleaving calibration effort
 - Gain & offset mismatch errors: signal frequency independent → easy to correct
 - Bandwidth & timing mismatch errors: signal frequency dependent → difficult to correct
- Impractical when # of channels is large
 - 😞 Large loading of front-end buffer
 - 😞 Very high & expensive interleaving calibration effort

CHOICE OF ARCHITECTURE: HIERARCHICAL INTERLEAVING

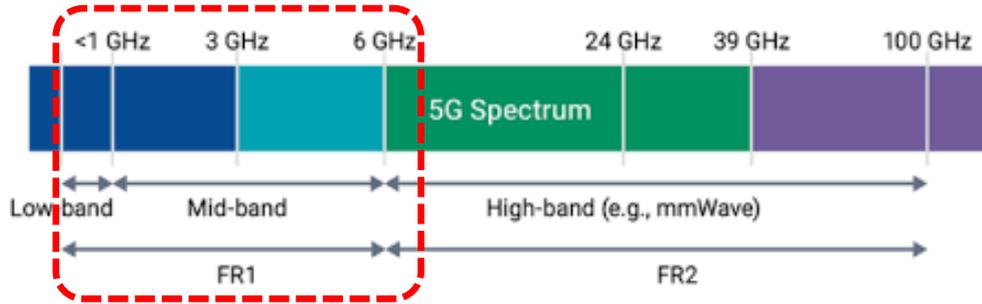


- Multi-level sampling hierarchy
 - 😊 Reduced loading of front-end buffer
 - 😊 Reduced number of samplers → simpler interleaving calibration
- Requires re-sampling & re-buffering
 - 😞 Additional power consumption
 - 😞 Noise & linearity degradation
 - 😞 Worse SNR-power tradeoff
- Choice of **interleaving architecture** must carefully balance these trade-offs

ILLUSTRATIVE USE CASE:
RF-SAMPLING ADC FOR 5G NR FRI BAND

RF-SAMPLING ADC FOR 5G NR FR1 BAND

ILLUSTRATIVE USE CASE

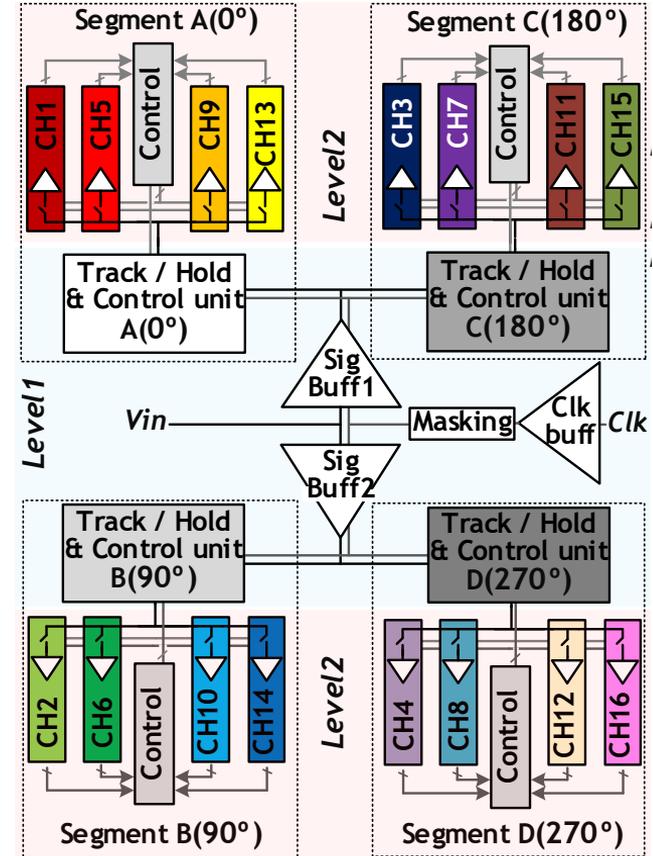


- Target specifications

- Bandwidth: > 5 GHz
- Effective resolution: > 56 dB SNDR (9 ENOB)
- Linearity: > 65 dB SFDR
- Sampling rate: > 16 GS/s
- Power consumption: < 1 W

- 16x time-interleaved RF-sampling ADC in 16nm FinFET

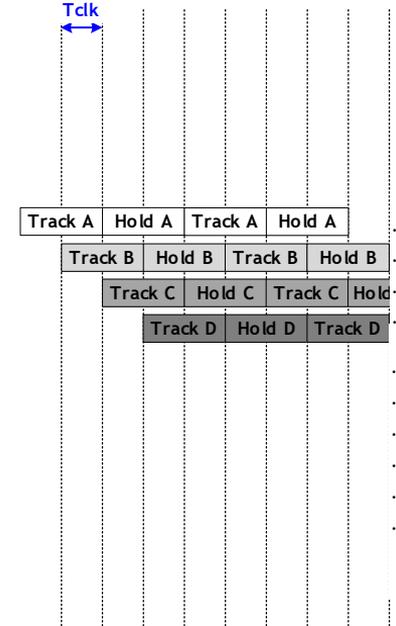
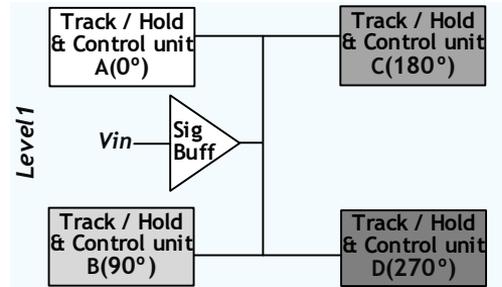
- Partially reported in [Markulic, VLSI'24]



ARCHITECTURE

4x4 HIERARCHICALLY-INTERLEAVED PIPELINED ADC

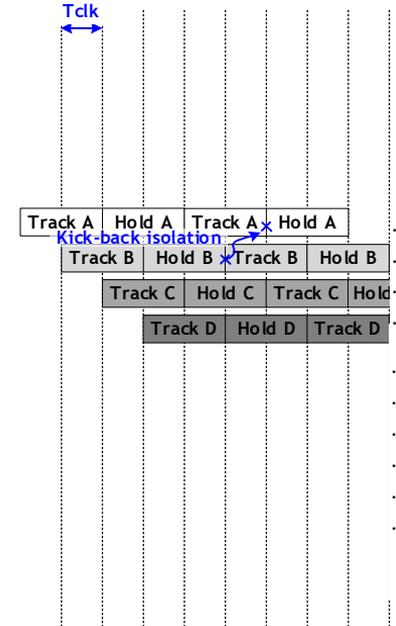
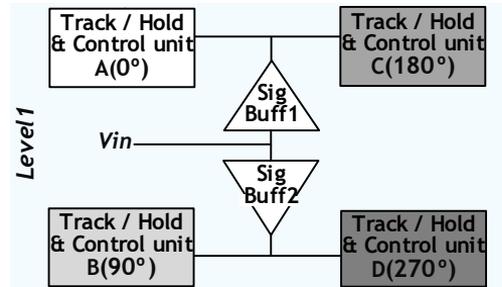
- 4 Front-end samplers @ 4GS/s
 - 50%-overlapped track time (2Ts)
 - Reduced interleaving calibration effort



ARCHITECTURE

4x4 HIERARCHICALLY-INTERLEAVED PIPELINED ADC

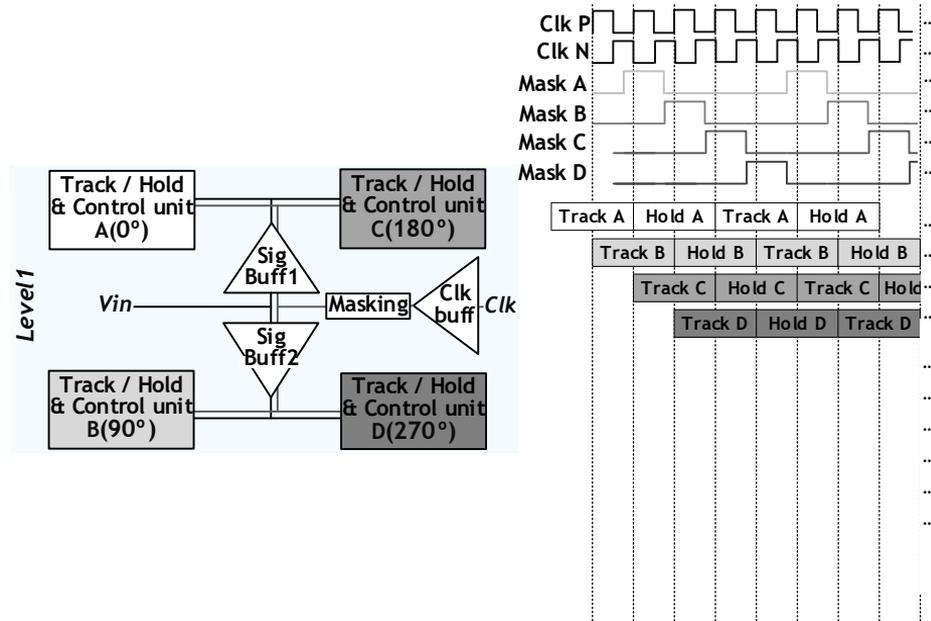
- 4 Front-end samplers @ 4GS/s
 - 50%-overlapped track time (2Ts)
 - Reduced interleaving calibration effort
- “Split” front-end buffer
 - Effective load = 1 sampler → lower power
 - Kick-back resilience



ARCHITECTURE

4x4 HIERARCHICALLY-INTERLEAVED PIPELINED ADC

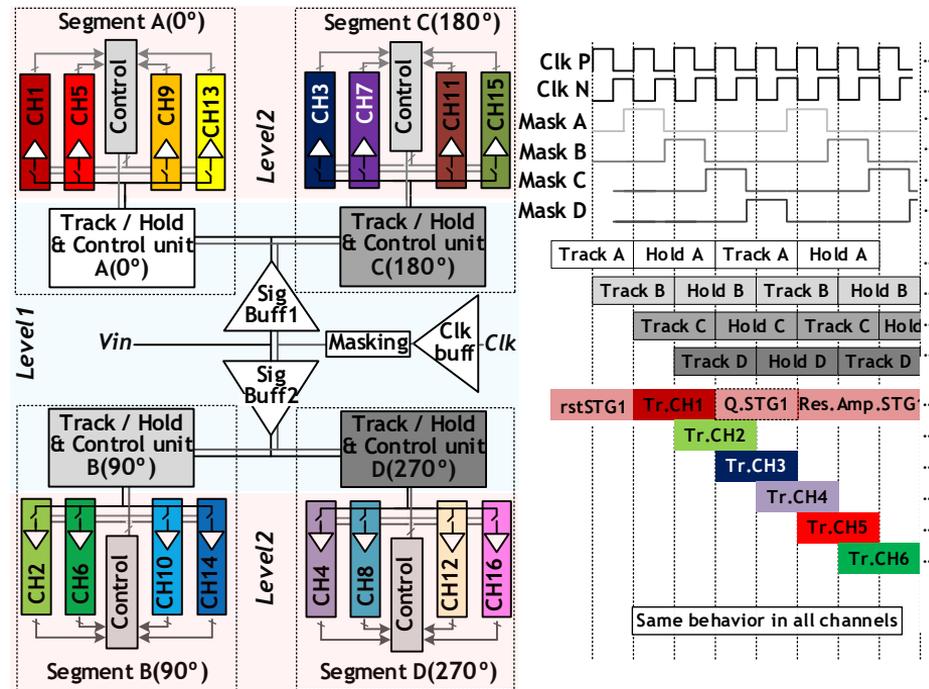
- 4 Front-end samplers @ 4GS/s
 - 50%-overlapped track time (2Ts)
 - Reduced interleaving calibration effort
- “Split” front-end buffer
 - Effective load = 1 sampler → lower power
 - Kick-back resilience
- 16 GS/s master CLK + interleaving masks
 - Edge-triggered sampling → immune to duty-cycle errors



ARCHITECTURE

4x4 HIERARCHICALLY-INTERLEAVED PIPELINED ADC

- 4 Front-end samplers @ 4GS/s
 - 50%-overlapped track time (2Ts)
 - Reduced interleaving calibration effort
- “Split” front-end buffer
 - Effective load = 1 sampler → lower power
 - Kick-back resilience
- 16 GS/s master CLK + interleaving masks
 - Edge-triggered sampling → immune to duty-cycle errors
- 16 interleaved ADC channels @ 1GS/s
 - Asynchronous operation (FSM-based)
 - No “deep” clock tree

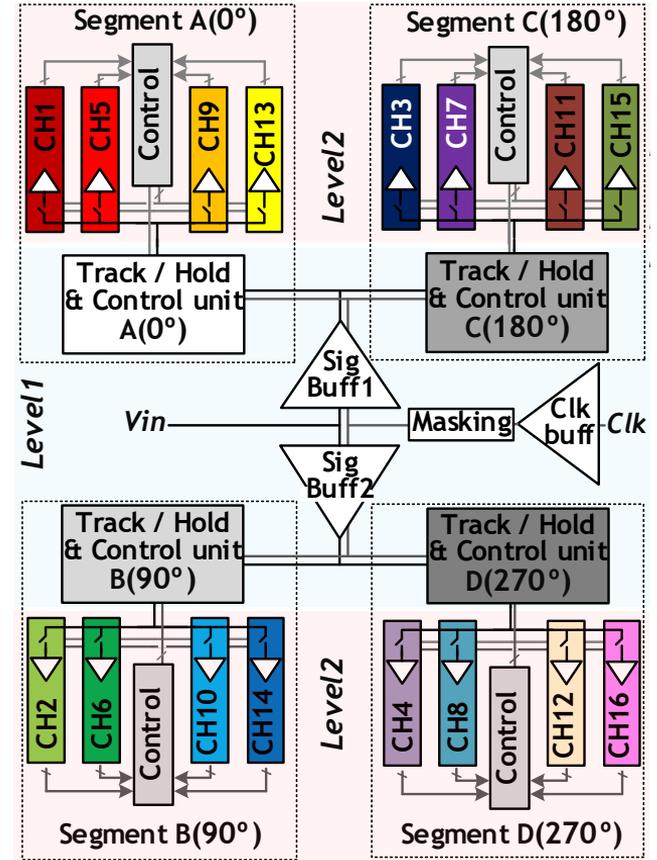


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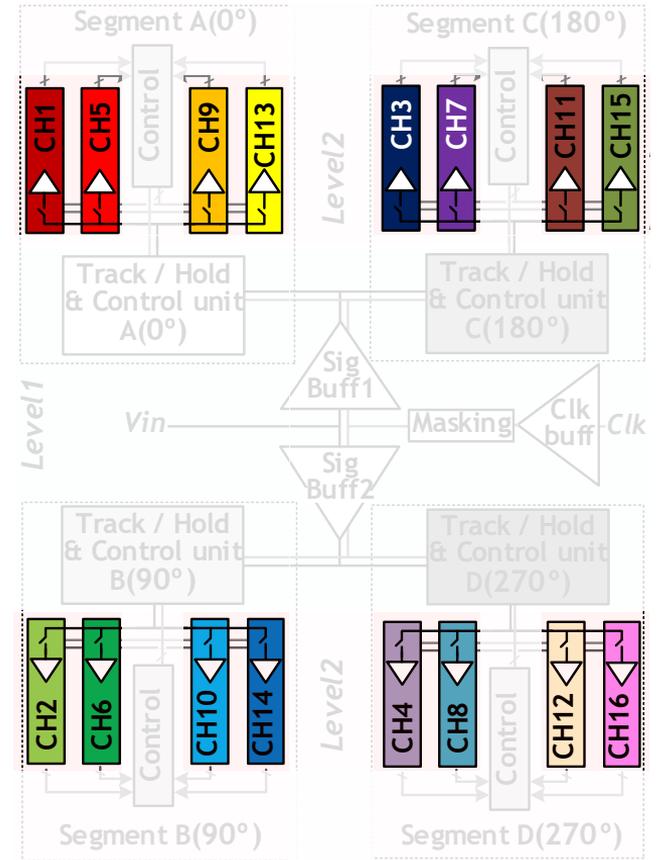
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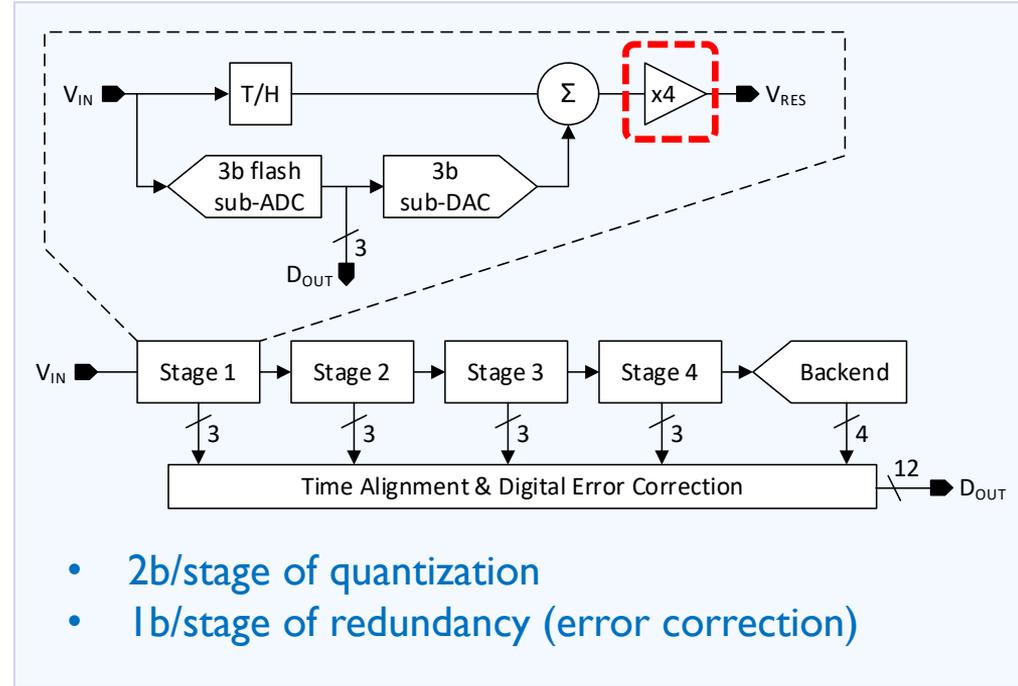
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PIPELINED ADC SUB-CHANNEL

- Pipelined architecture
 - Break conversion into smaller tasks
 - Pass incomplete result (“residue”) to next stage for more processing
 - Stages **operate concurrently**
 - → High-speed → used in all medium / high resolution GS/s ADCs
- Goal: minimize # of operations in critical timing path
 1. Sampling
 2. Quantization
 3. Residue generation & **amplification**
 - **Speed & linearity bottleneck**

Example 3b/stage Pipelined ADC



CHANNEL TECHNIQUE #1: RINGAMP-BASED POWER-EFFICIENT RESIDUE AMPLIFICATION

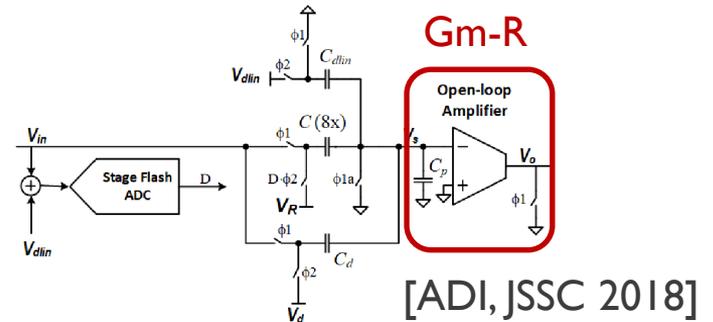
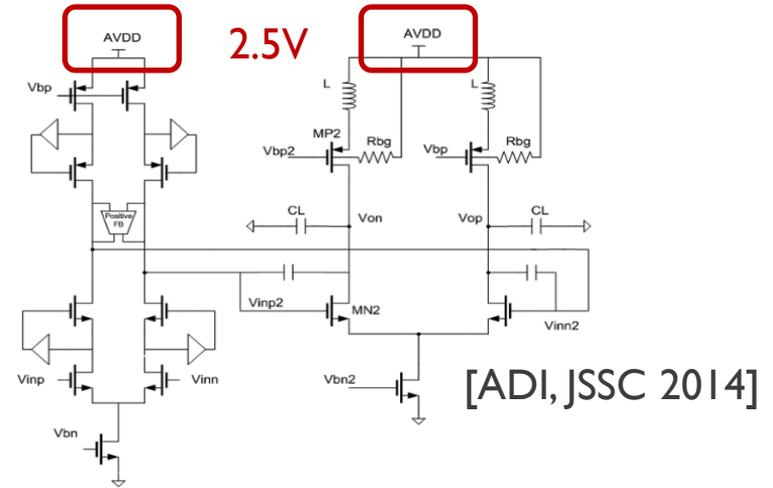
RESIDUE AMPLIFICATION: THE HIDDEN BOTTLENECK

- **Class-A opamps** in nanoscale CMOS

- 😞 Not enough voltage headroom
- 😞 Require special high-voltage supply
- 😞 Severely degrades power efficiency

- **Open-loop amplifiers** in nanoscale CMOS (Gm-R, Gm-C)

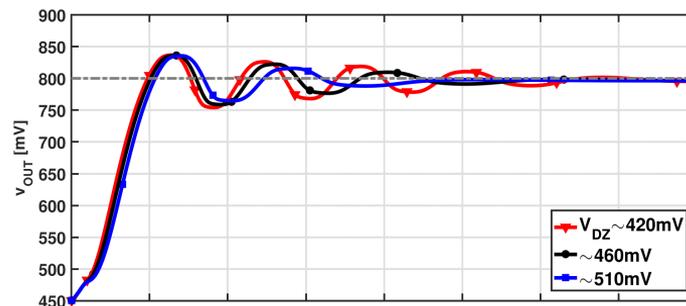
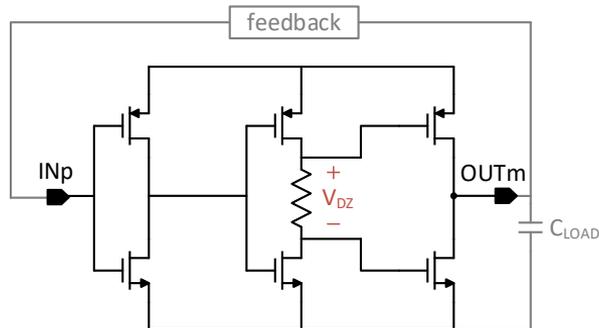
- 😊 Fast & power efficient but ...
- 😞 Limited voltage swing → poor SNR
- 😞 Low-linearity limitations



OUR APPROACH: LEVERAGE THE RING AMPLIFIER (RINGAMP)

- Basic idea: stabilize 3-stage closed-loop amplifier by dynamically forming a dominant output pole
 - Several ways to implement this
- Several advantages for discrete-time amplification
 - 😊 High efficiency
 - 😊 High speed
 - 😊 Wide output swing
 - 😊 Excellent linearity
 - 😊 Scales with digital
 - 😊 Fully-dynamic (i.e. switchable)
 - 😊 PVT-robust (modern implementations)

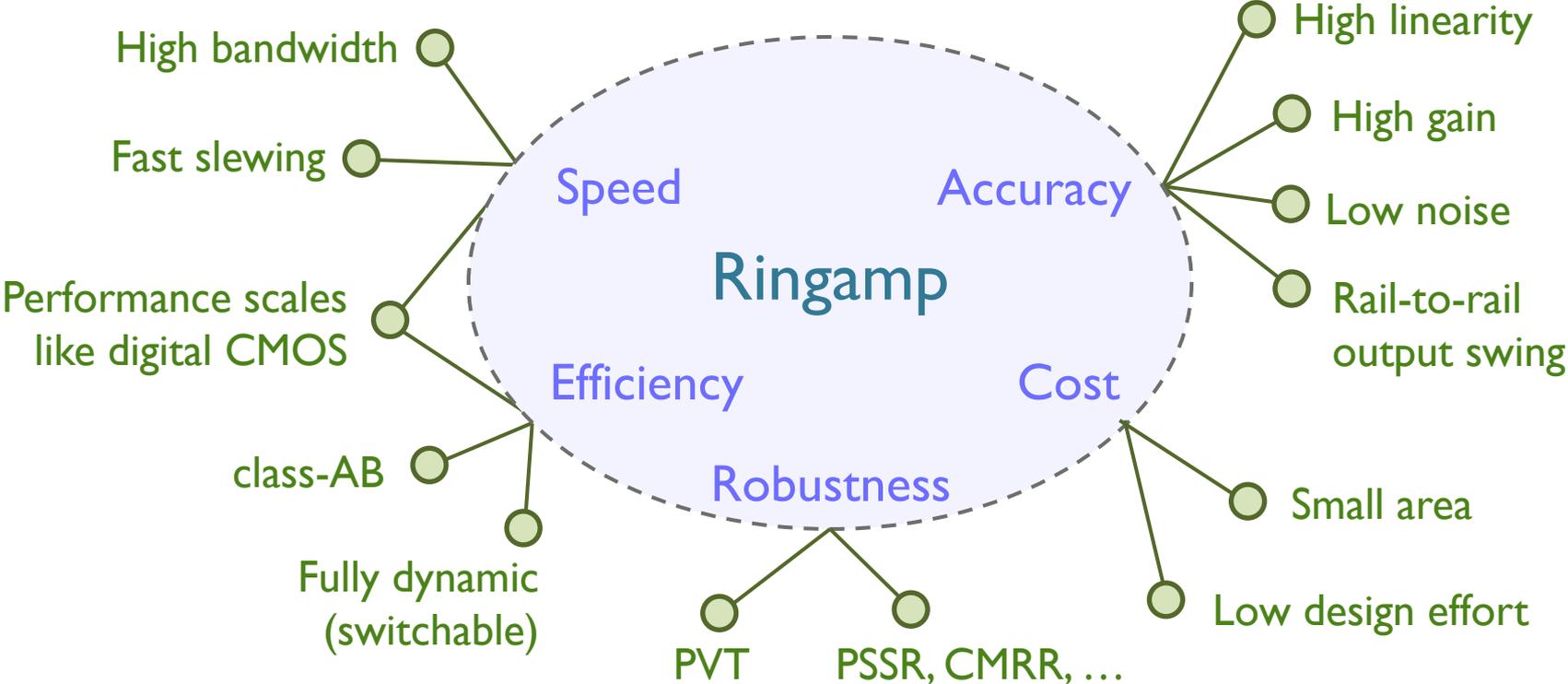
[Lim, JSSC 2015]



[Lagos, JSSC 2019]

RING AMPLIFIER: A CLOSE-TO-IDEAL DISCRETE-TIME AMPLIFIER

HIGH-PERFORMANCE, POWER-EFFICIENT AMPLIFICATION



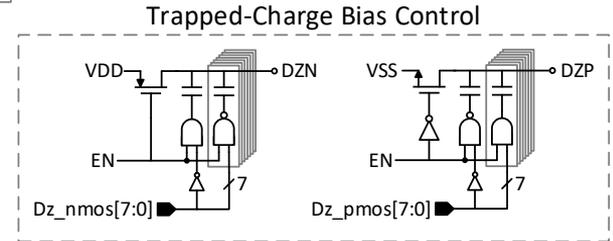
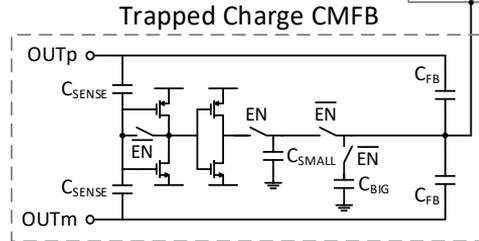
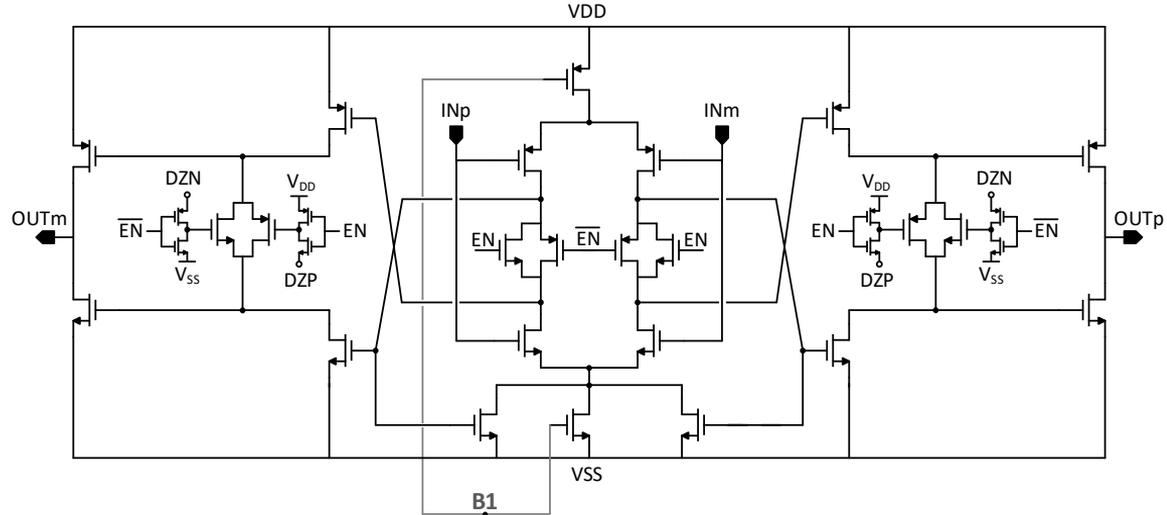
RING AMPLIFIER – PRACTICAL IMPLEMENTATION

[Hershberg, VLSI'20], [Hershberg, JSSC'21]

Imec IGS/s ADC channel

F_s	I GS/s
ENOB	10 bit
SNDR	62 dB
SFDR	75 dB
Power	12 mW
FoM_W	11.7 fJ/cs

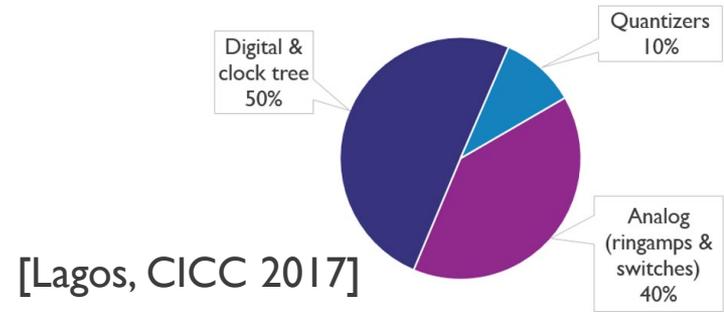
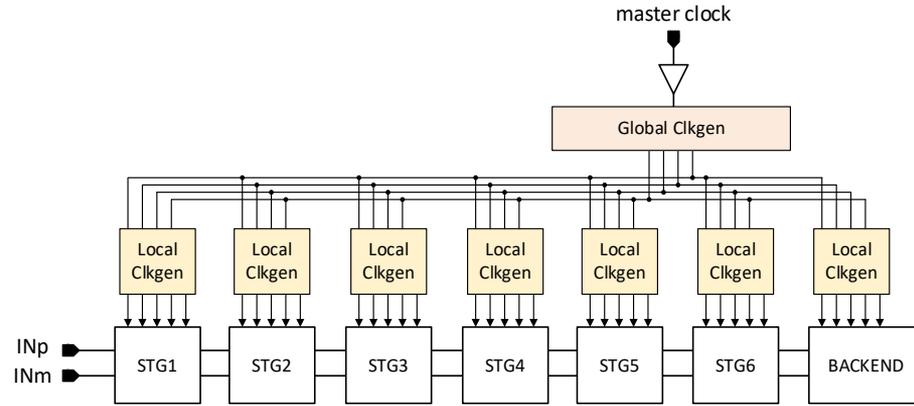
- Order-of-magnitude efficiency improvement w.r.t. SotA
 - [imec, JSSCC'21]: 36 amplifiers
 - [imec, VLSI'24]: 144 amplifiers



CHANNEL TECHNIQUE #2: ASYNCHRONOUS TIMING FOR POWER-EFFICIENT CLOCKING

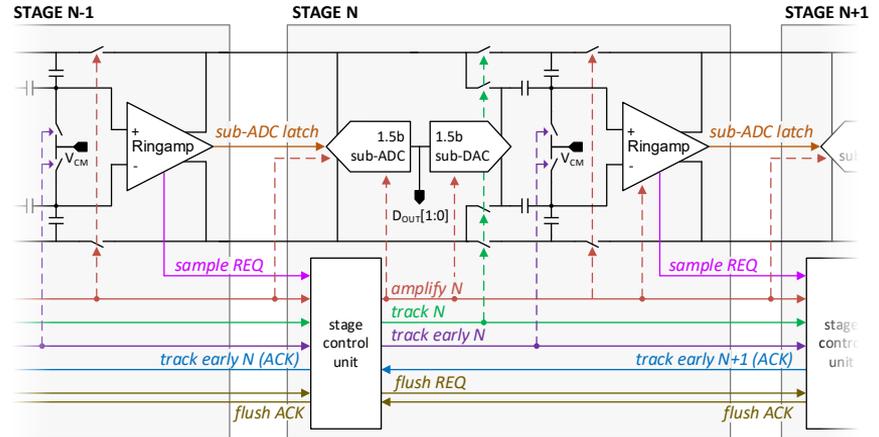
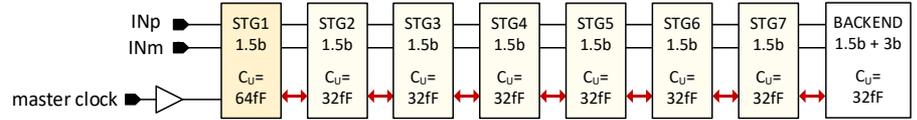
CLASSICAL CLOCK TREE IN DEEP PIPELINED ADCs

- Power & speed bottleneck
 - ☹ Many independent branches:
 - ☹ Mismatch / parasitics / skew
 - ☹ Needs timing margin for reliable operation
 - ☹ Must respect causal timing relationships
 - ☹ Guarantee non-overlapping clock phases
 - ☹ Exponentially more difficult @ high speeds
- Difficult design tradeoffs
 - ☹ Power / speed / jitter / reliability
- After ringamps solve amplifier bottleneck, clocking becomes the new bottleneck
 - Clock-tree power becomes dominant



OUR APPROACH: ASYNCHRONOUS CHANNEL OPERATION (I)

- Asynchronous, event-driven timing control applied to deep pipelines
- Two parallel paths in a pipeline
 - Analog signal path
 - Digital control clock path
- Digital control path: “Stage Control Units”
 - Finite-state-machine-based
 - Orchestrate stage local-events
 - Communicate to the next/previous stage
- In a nutshell:
 - Synchronous edge-triggered sampling event
 - ...then internal asynchronous operation



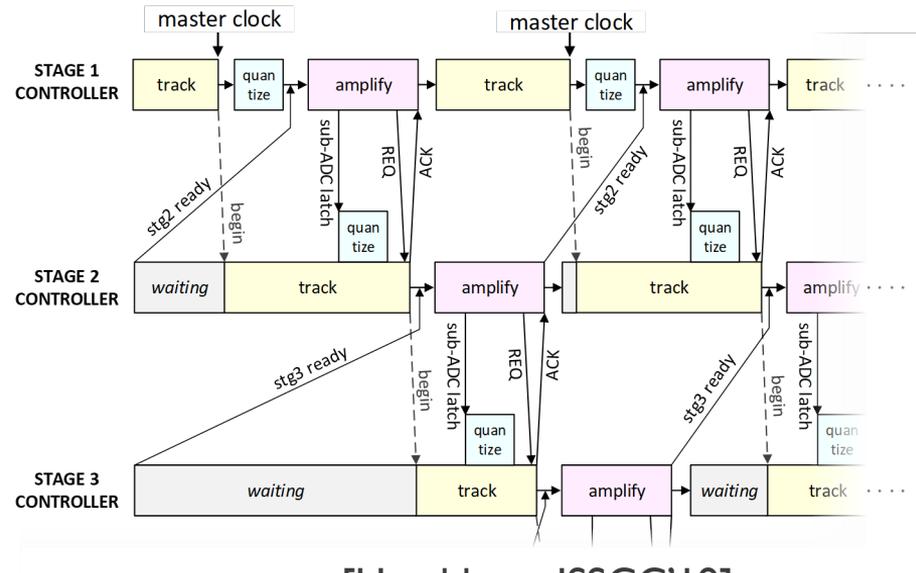
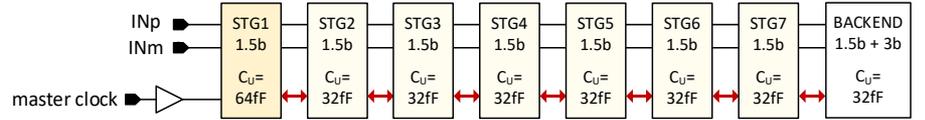
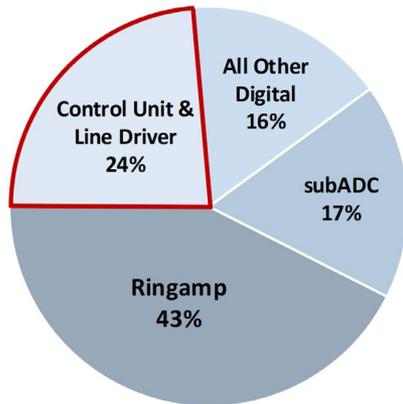
[Hershberg, ISSCC'19]

[Hershberg, T-CASI'21]

OUR APPROACH: ASYNCHRONOUS CHANNEL OPERATION (2)

- Mostly only advantages

- ☺ Minimal global routing
- ☺ Correct-by-construction timing
- ☺ Easy reconfigurability
- ☺ Faster operation (less “wasted” time)
- ☺ Lower power
- ☺ Verification: handle dead-locks with care

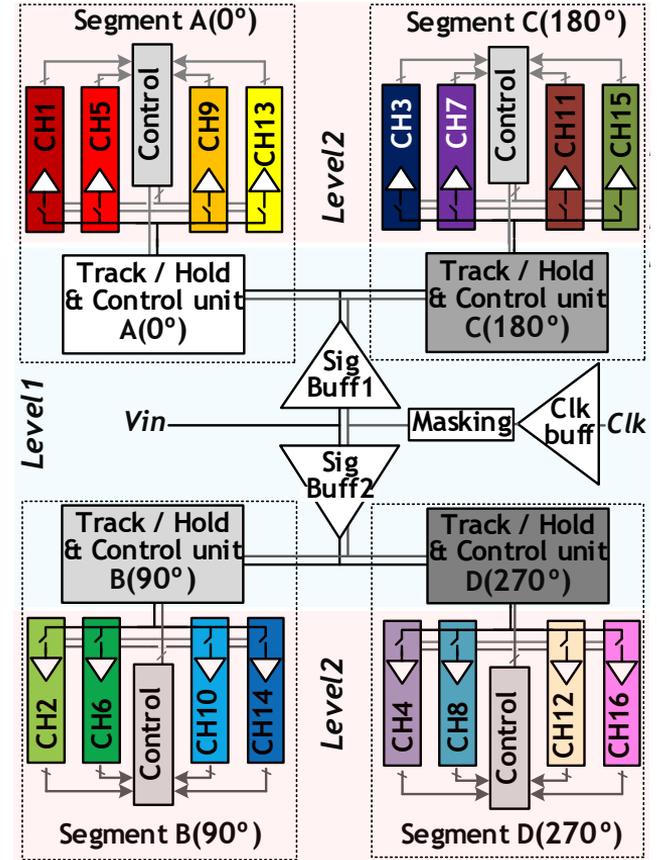


[Hershberg, ISSCC'19]

[Hershberg, T-CASI'21]

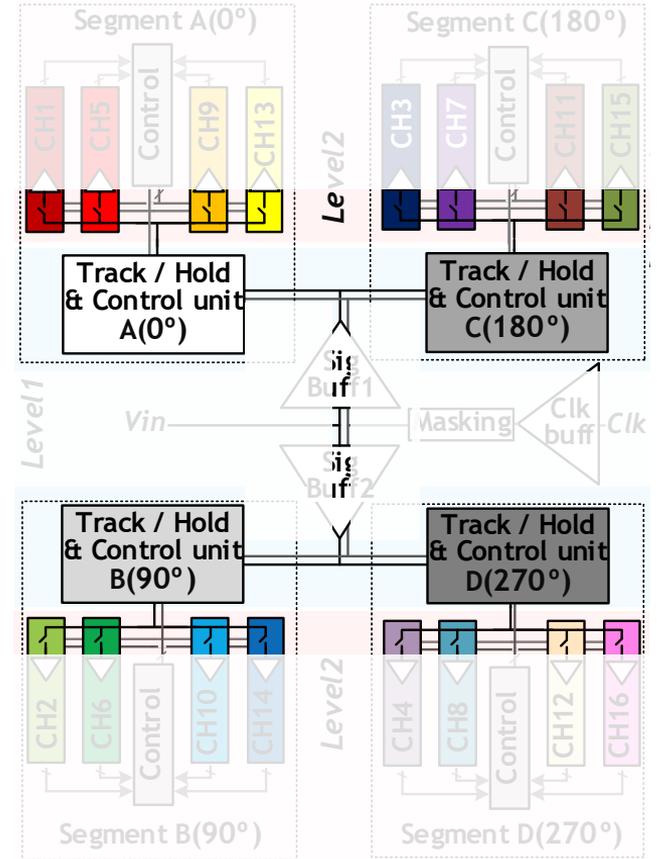
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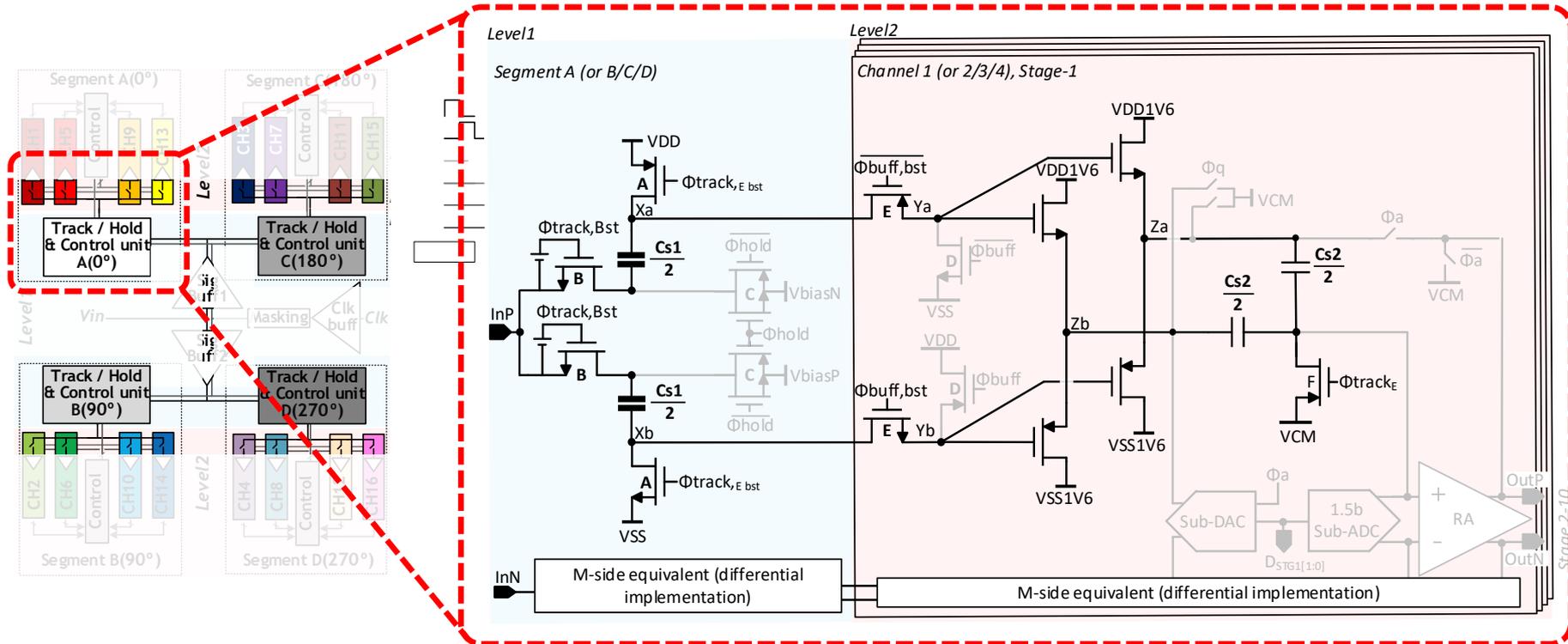
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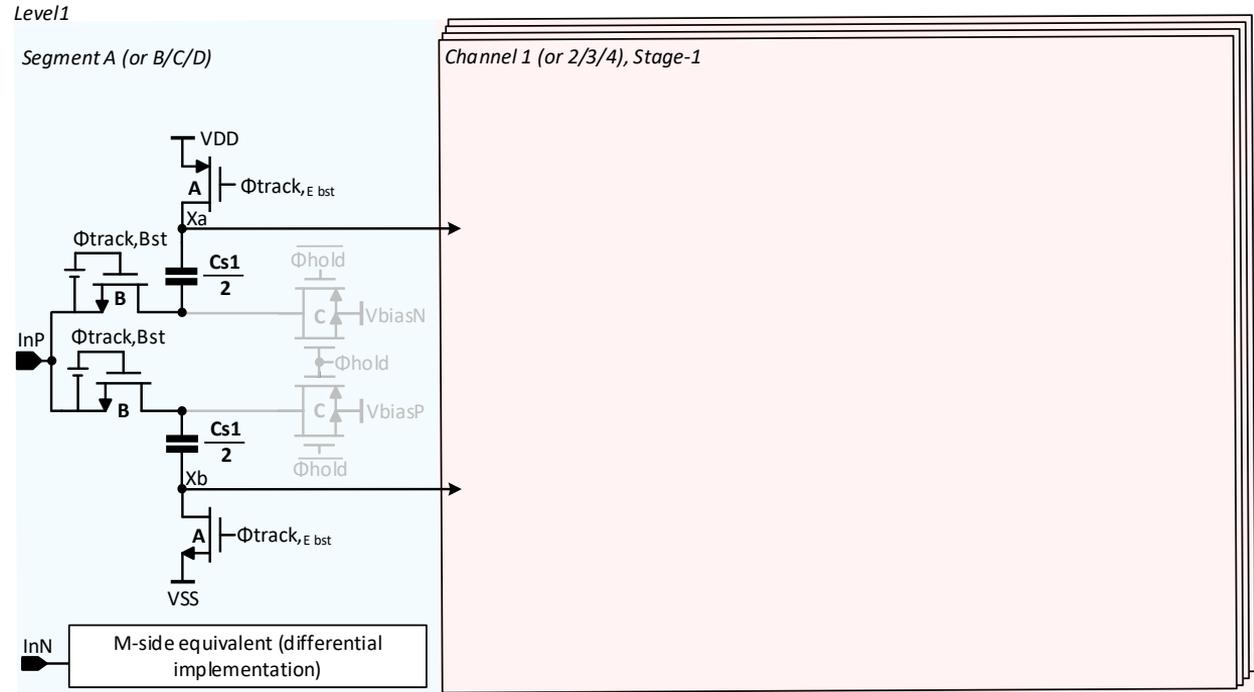
HIERARCHICAL INTERLEAVING – OVERVIEW

2-LEVEL INTERLEAVING ARCHITECTURE



HIERARCHICAL INTERLEAVING – LEVEL I DETAILS

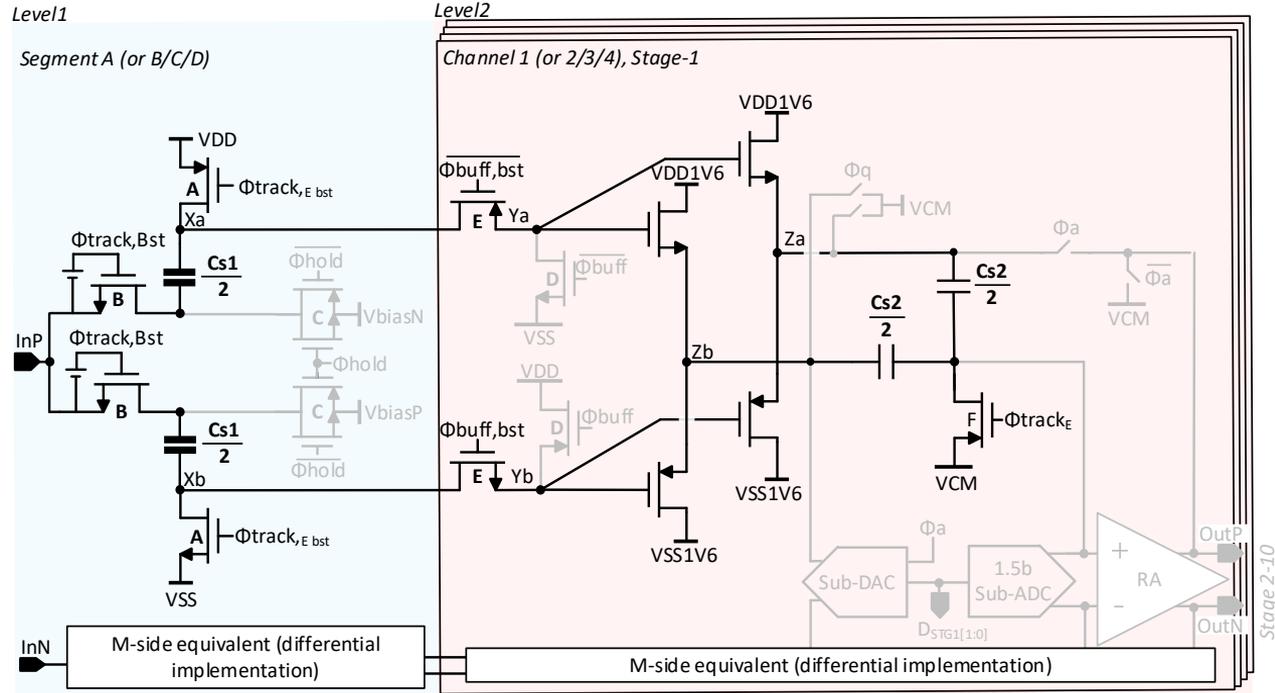
- Novel “split” sampling capacitor architecture
- High-linearity
 - Bottom-plate sampling
 - Bootstrapped top-plate switch
- Low-noise
 - Large sampling capacitor $C_{S1} = 600$ fF



HIERARCHICAL INTERLEAVING – LEVEL 2 DETAILS

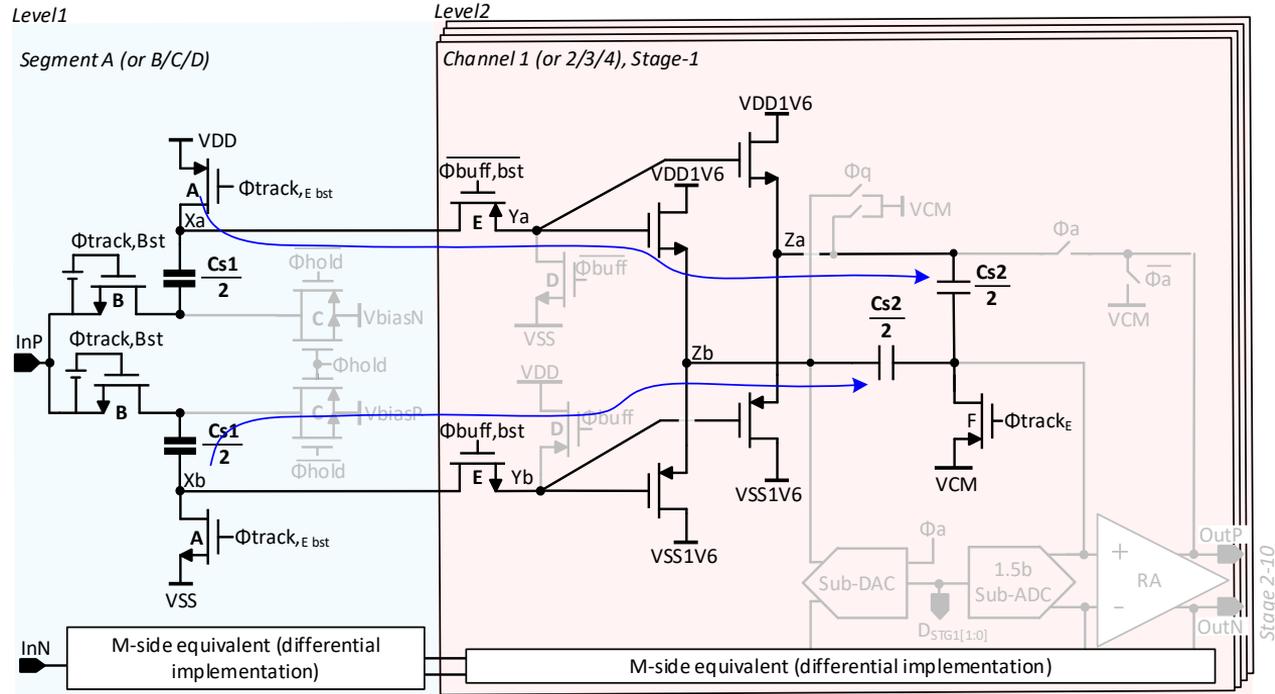
- High speed & linearity

- Dynamic push-pull source follower
 - Re-used as top-plate switch
- Bottom plate sampling
- Isolation switch “E”



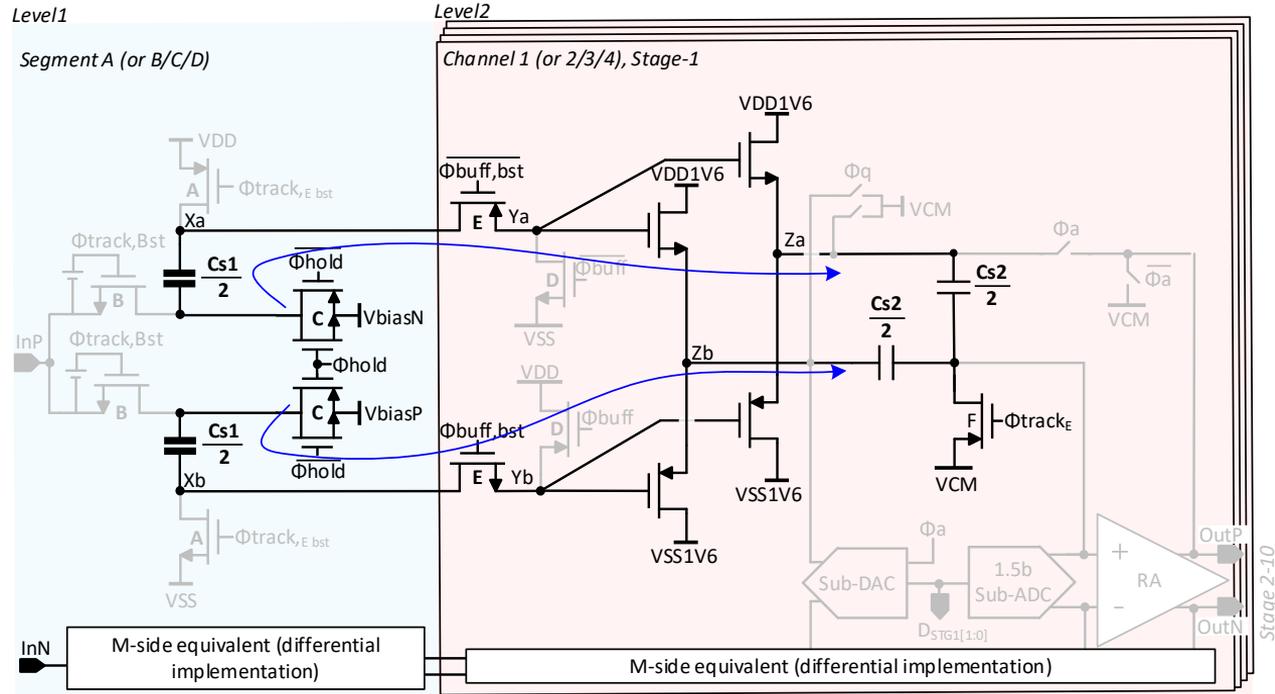
HIERARCHICAL INTERLEAVING – OPERATION (1/5)

- Level 1: tracking
- Level 2: clearing C_{S2}
 - Clears previous sample → no memory effects
 - Level-2 buffer is ON → no power-up timing overhead in next phase
- Other channels in same segment isolated by switch “E”



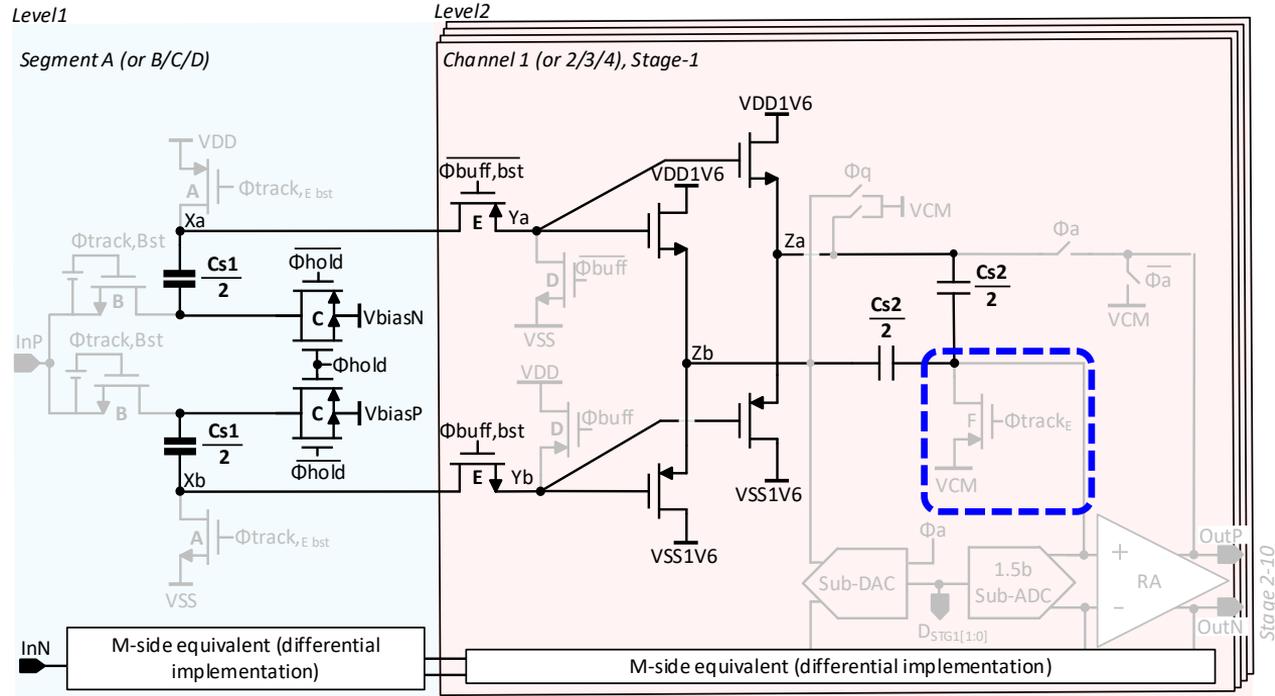
HIERARCHICAL INTERLEAVING – OPERATION (2/5)

- Level 1: holding
- Level 2: tracking
- Split C_{s1} used for
 - Sampling
 - Buffer biasing
- Level-2 tracking starts immediately (buffer was already ON)



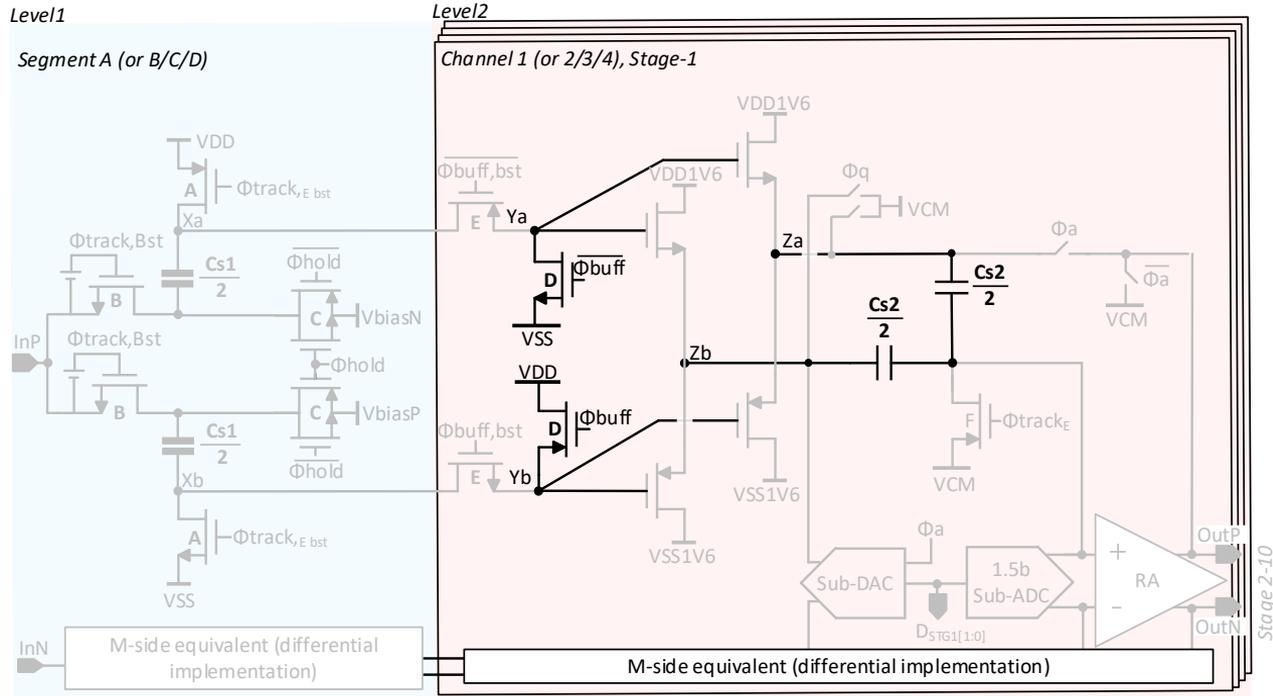
HIERARCHICAL INTERLEAVING – OPERATION (3/5)

- Level 1: holding
- Level 2: sample
 - Bottom-plate sampling



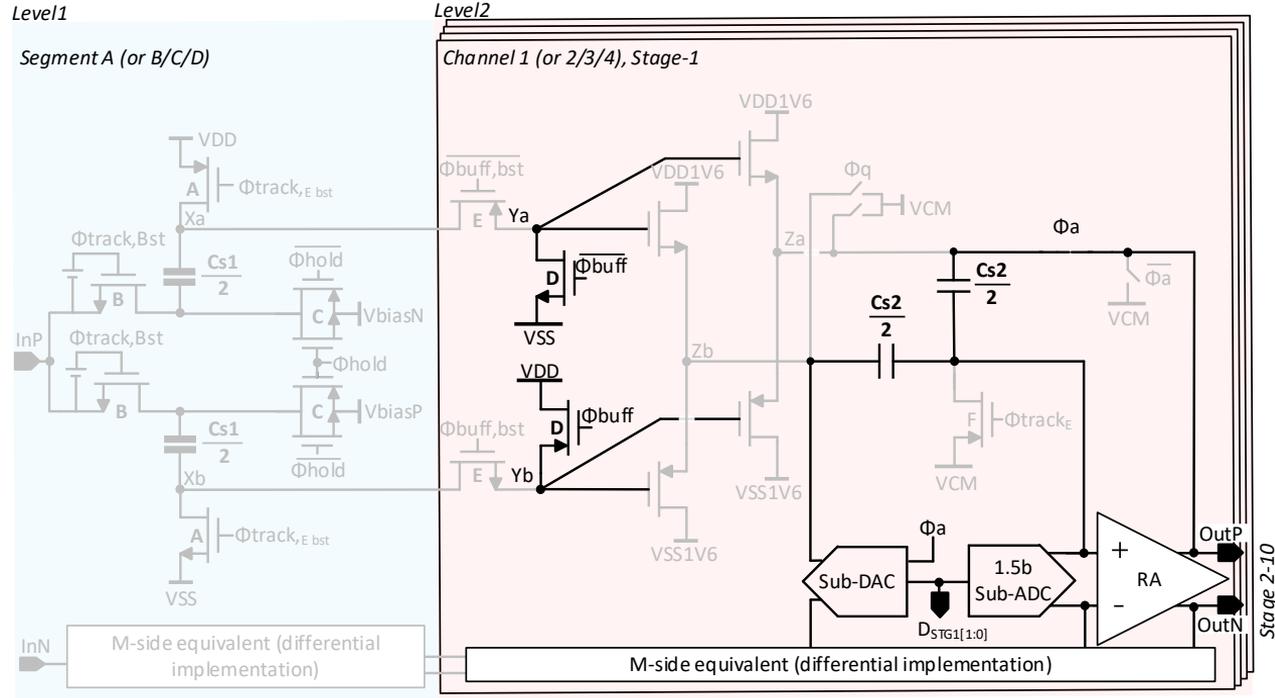
HIERARCHICAL INTERLEAVING – OPERATION (4/5)

- Level 1: tracking & holding
 - Acts as top-plate SW
 - Power saving
- Level 2: buffer turns OFF
 - Switch “E” opens to isolate Level-1



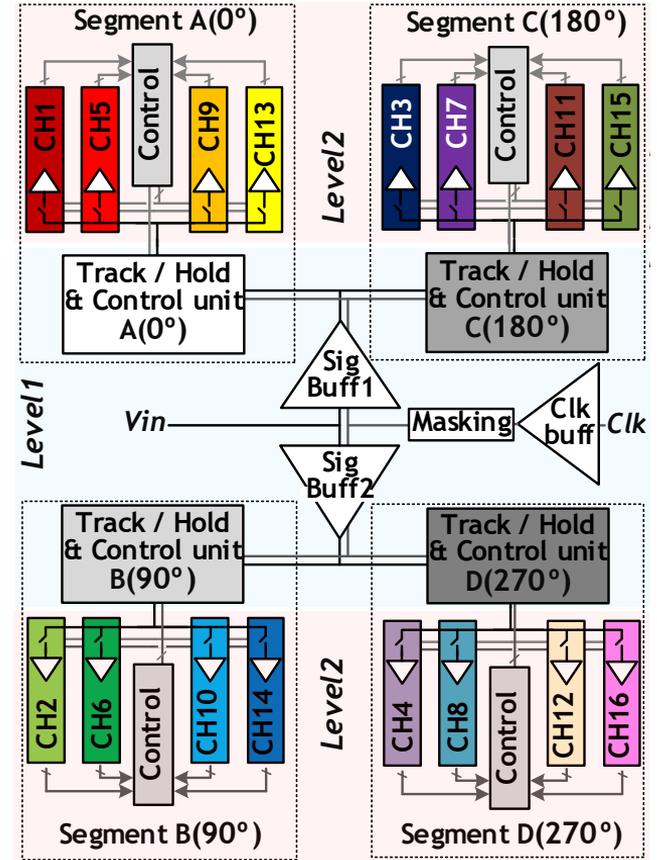
HIERARCHICAL INTERLEAVING – OPERATION (5/5)

- Level 1: tracking & holding
- Level 2: quantization & residue amplification
 - Channel operates w/ asynchronous timing as previously described
- ∴ Efficient hierarchical interleaving architecture
 - simultaneously achieves low noise & high linearity



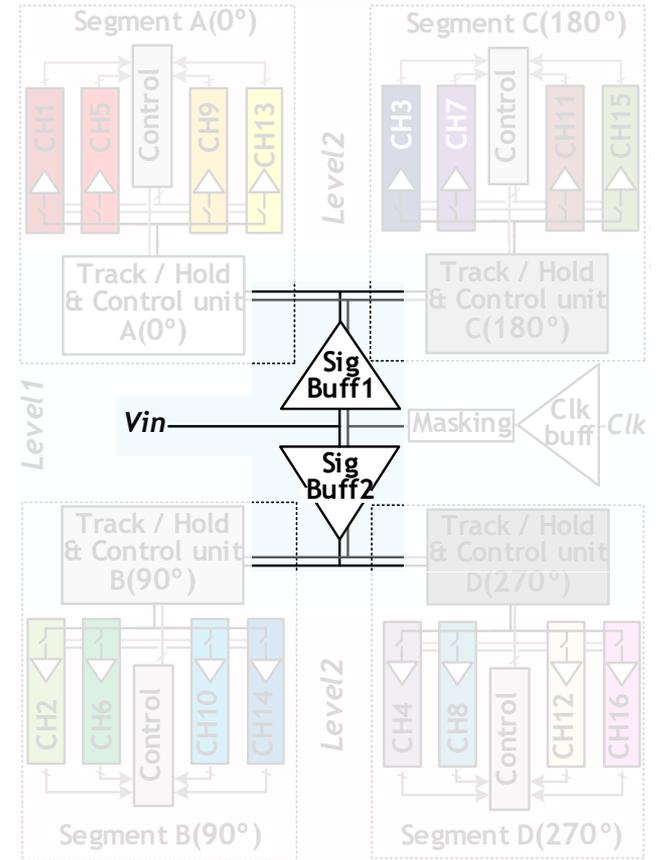
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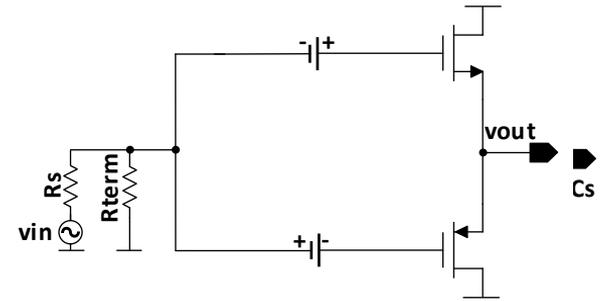
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HIGH-LINEARITY WIDEBAND FRONT-END BUFFER

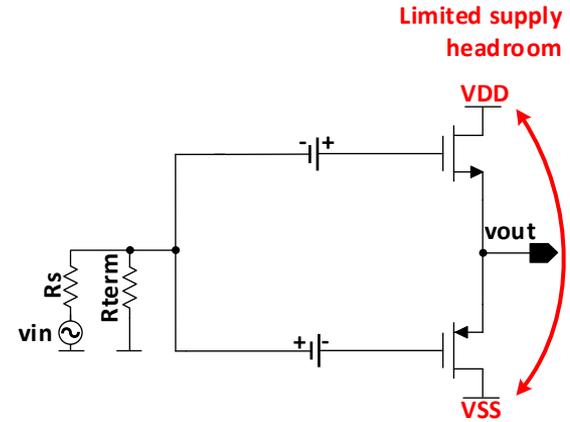
PUSH-PULL SOURCE FOLLOWER



HIGH-LINEARITY WIDEBAND FRONT-END BUFFER

PUSH-PULL SOURCE FOLLOWER

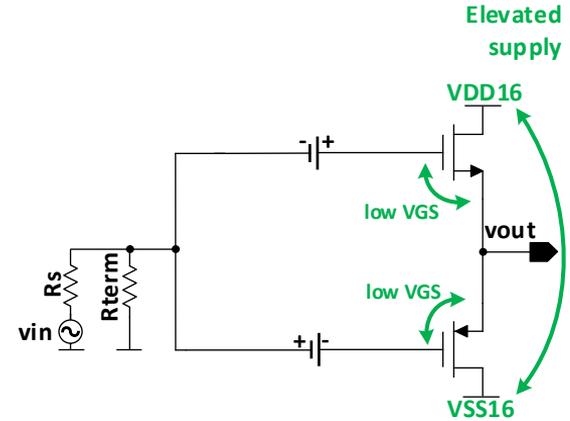
- Frequency-independent (i.e. static) distortion
 - Limited supply headroom



HIGH-LINEARITY WIDEBAND FRONT-END BUFFER

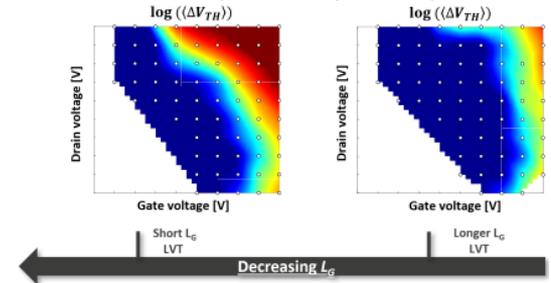
PUSH-PULL SOURCE FOLLOWER

- Frequency-independent (i.e. static) distortion
 - Limited supply headroom → solved by increasing supply



Aging models predict >10y life-span.

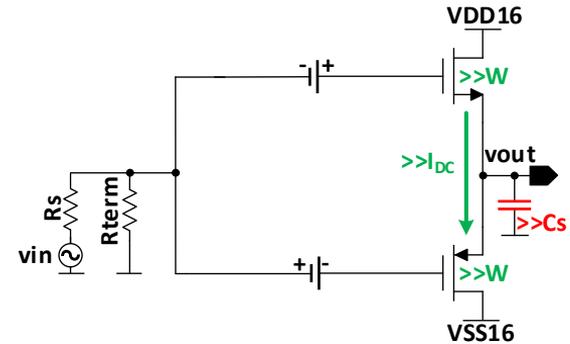
**[Intentional use of unitless data]*



HIGH-LINEARITY WIDEBAND FRONT-END BUFFER

PUSH-PULL SOURCE FOLLOWER

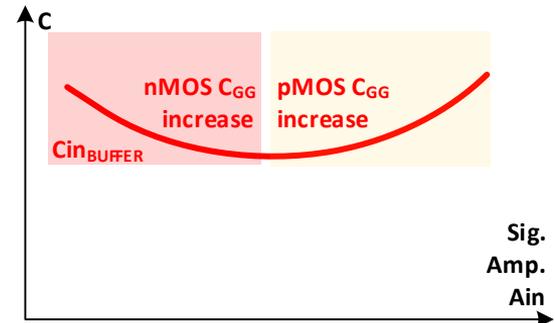
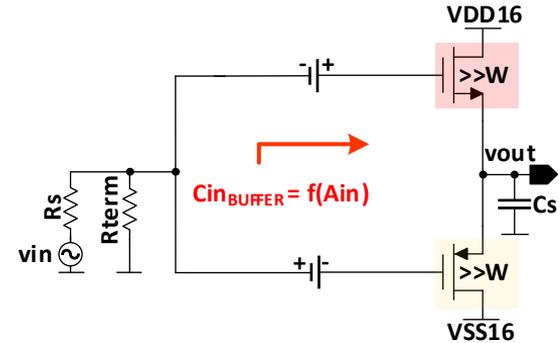
- Frequency-independent (i.e. static) distortion
 - Limited supply headroom → solved by increasing supply
- Frequency-dependent distortion
 - Slewing @ HF w/ large load → solved by increasing I_{BIAS}



HIGH-LINEARITY WIDEBAND FRONT-END BUFFER

PUSH-PULL SOURCE FOLLOWER

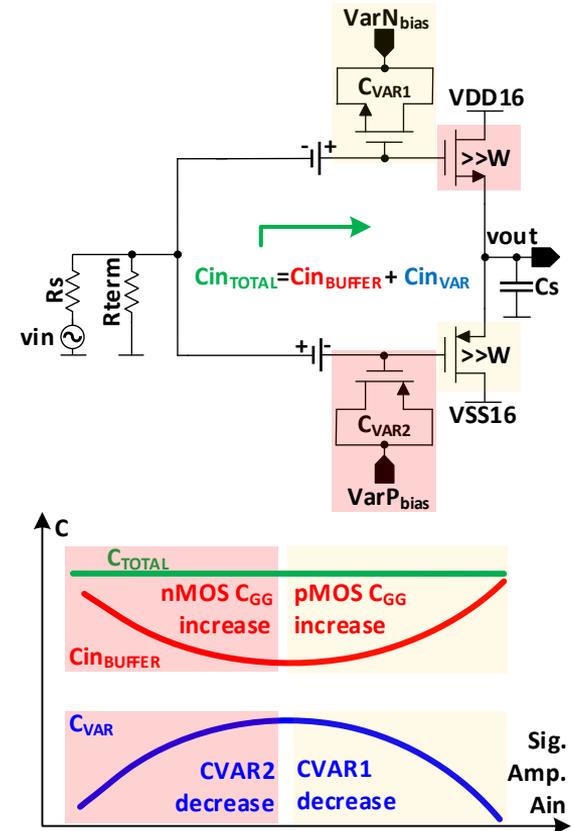
- Frequency-independent (i.e. static) distortion
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 - Signal-dependent bandwidth → dynamic distortion



HIGH-LINEARITY WIDEBAND FRONT-END BUFFER

PUSH-PULL SOURCE FOLLOWER

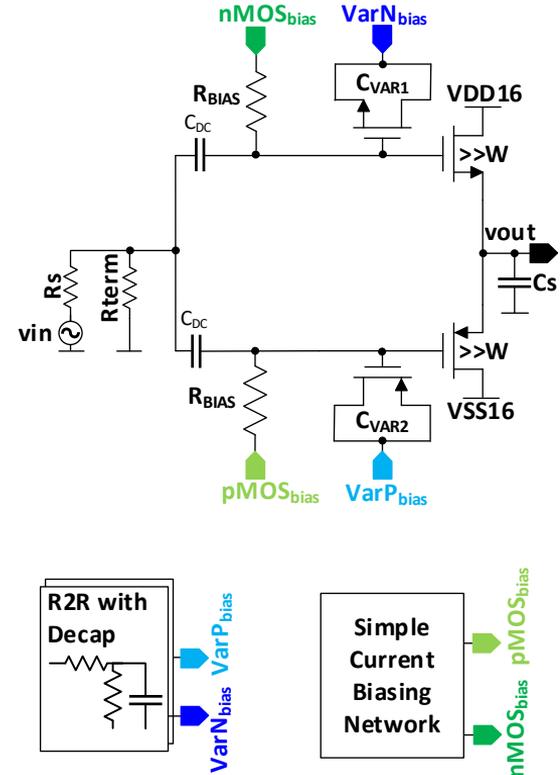
- Frequency-independent (i.e. static) distortion
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- Varactor-based nonlinear-capacitance compensation
 - NMOS varactor compensates PMOS-induced distortion
 - PMOS varactor compensates NMOS-induced distortion
 - Simple biasing (high impedance node)



HIGH-LINEARITY WIDEBAND FRONT-END BUFFER

PUSH-PULL SOURCE FOLLOWER

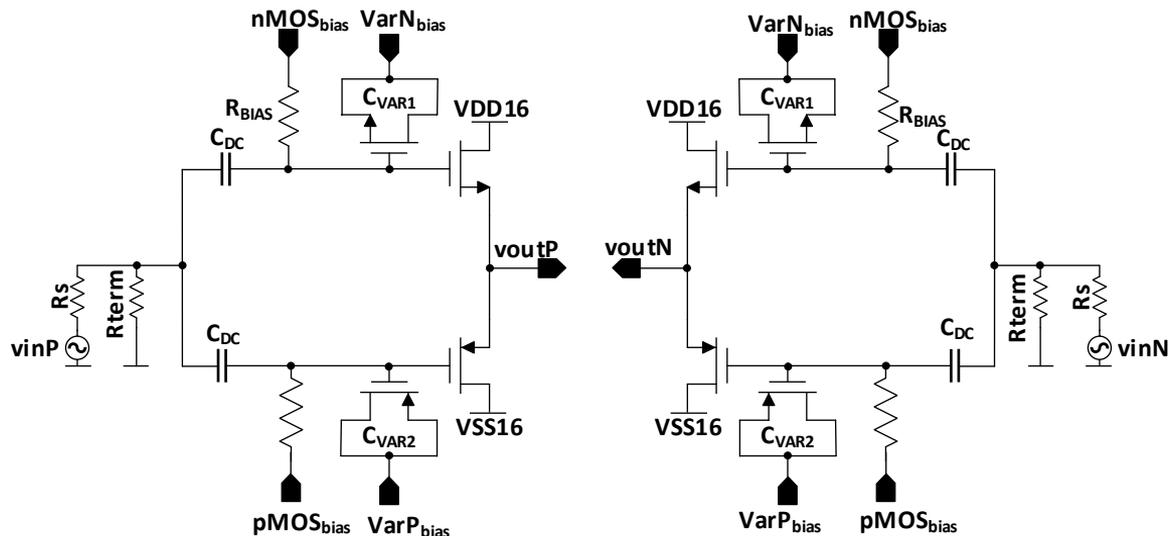
- Frequency-independent (i.e. static) distortion
 - Limited supply headroom \rightarrow solved by increasing supply
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 - Signal-dependent input capacitance
 - Signal-dependent bandwidth \rightarrow dynamic distortion
- Varactor-based nonlinear-capacitance compensation
 - NMOS varactor compensates PMOS-induced distortion
 - PMOS varactor compensates NMOS-induced distortion
 - Simple biasing (high impedance node)
- Current-biased environment for PVT robustness
 - Same-type MOS devices share gate terminal



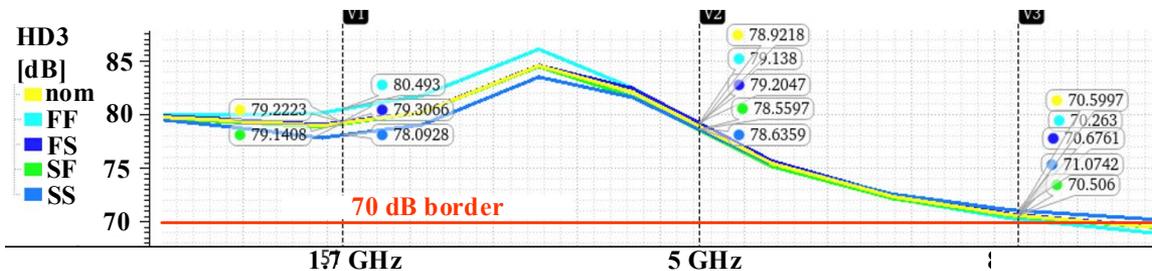
HIGH-LINEARITY WIDEBAND FRONT-END BUFFER

PUSH-PULL SOURCE FOLLOWER

- Pseudo-differential implementation



- PVT-robust wideband distortion compensation

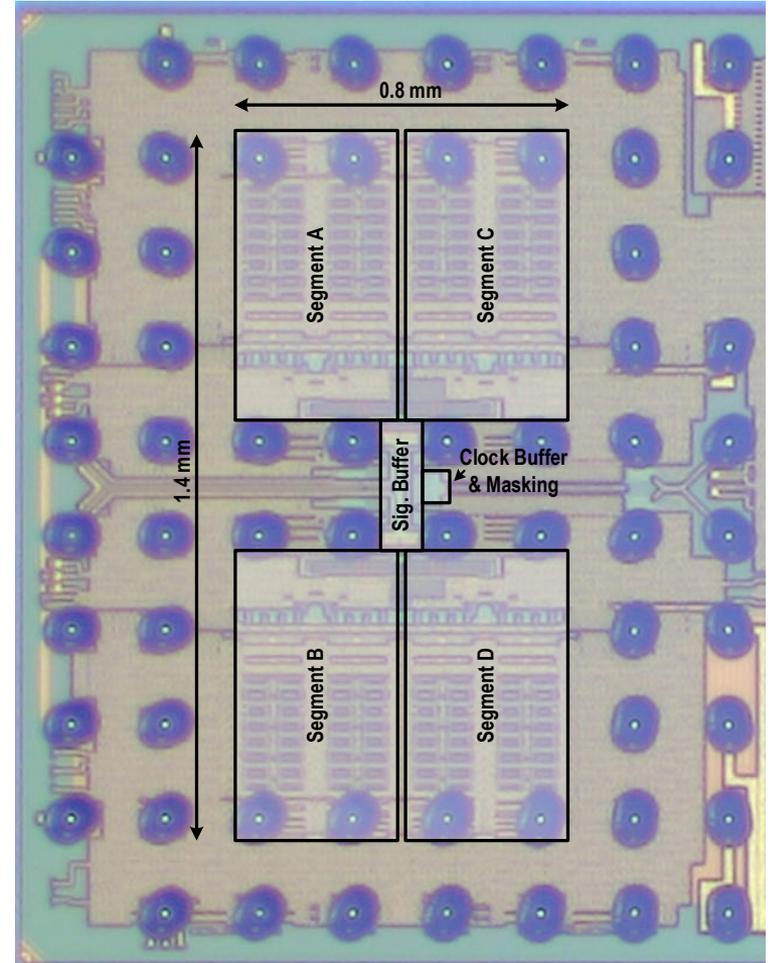


CONTENTS

- Motivation
- RF-sampling ADCs: challenges & tradeoffs
- Key technologies enabling high-performance, power-efficient RF-sampling ADCs
 1. Fast & power-efficient channel
 2. Signal-integrity-preserving hierarchical interleaving
 3. High-linearity, wideband front-end buffer
- **Recent experimental results**
- Conclusions

IMPLEMENTED PROTOTYPE

- 16-nm FinFET CMOS
- Core area: 0.8 x 1.4 (~1.1 mm²)
- Supplies:
 - Input buffer: 1.65 V
 - Everything else: 0.9 V
- References:
 - $V_{REF,P} / V_{REF,N}$: 750 mV / 150 mV
 - I_{BIAS} : 100 μ A

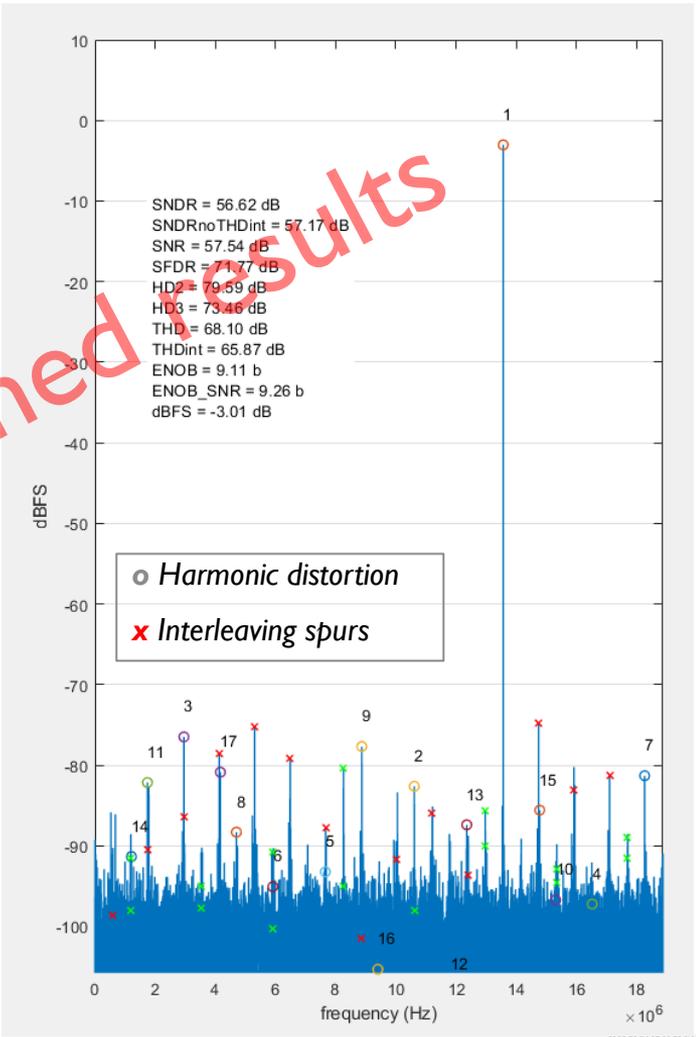


MEASURED PERFORMANCE @ 16.5 GS/s

OUTPUT SPECTRUM w/ LF INPUT SIGNAL

- $F_{in} = 100$ MHz
- $P_{in} = -3$ dBFs
- Decimated by 4037

- 9.11-b ENOB (56.6-dB SNDR)
- 72-dB SFDR



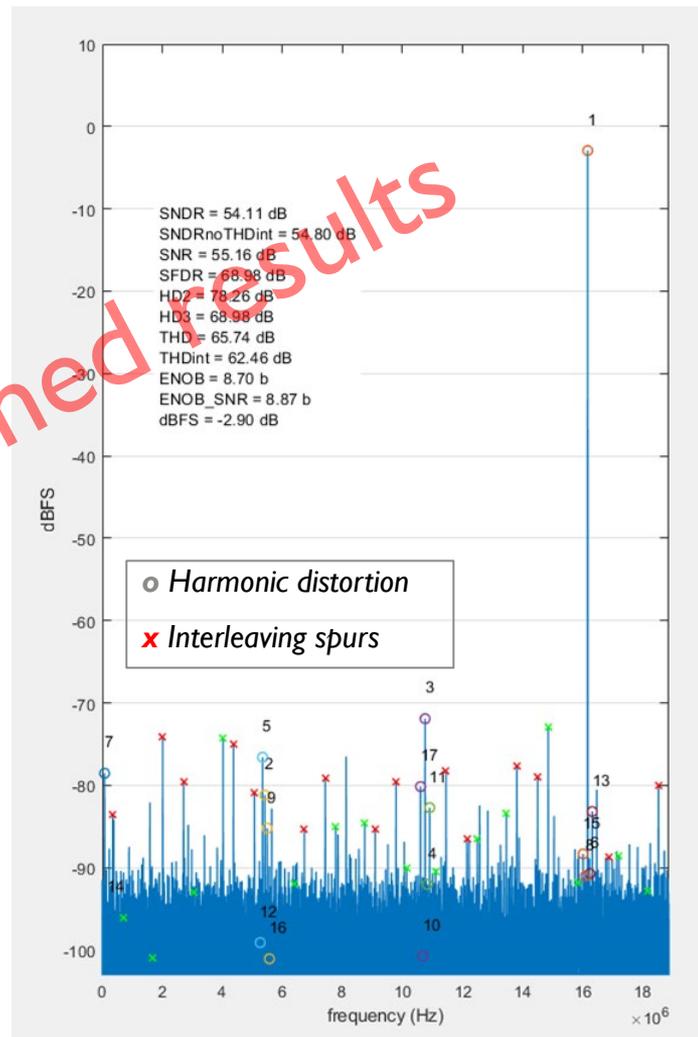
Confidential unpublished results

MEASURED PERFORMANCE @ 16.5 GS/s

OUTPUT SPECTRUM w/ HF INPUT SIGNAL

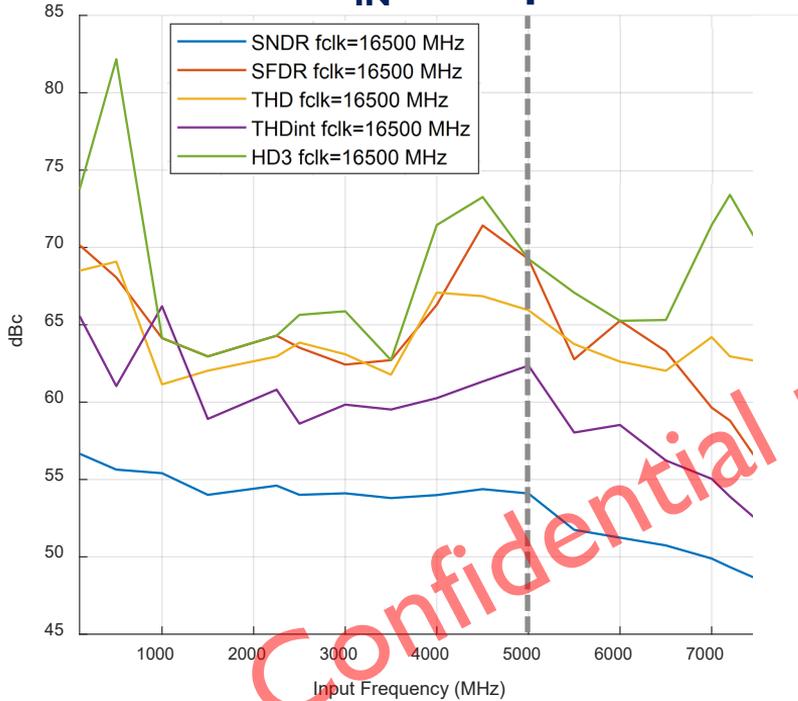
- $F_{in} = 5$ GHz
- $P_{in} = -3$ dBFs
- Decimated by 4037

- 8.7-b ENOB (54.1-dB SND)
- 69-dB SFDR (HD3-dominated)
- All interleaving spurs < -75-dBc

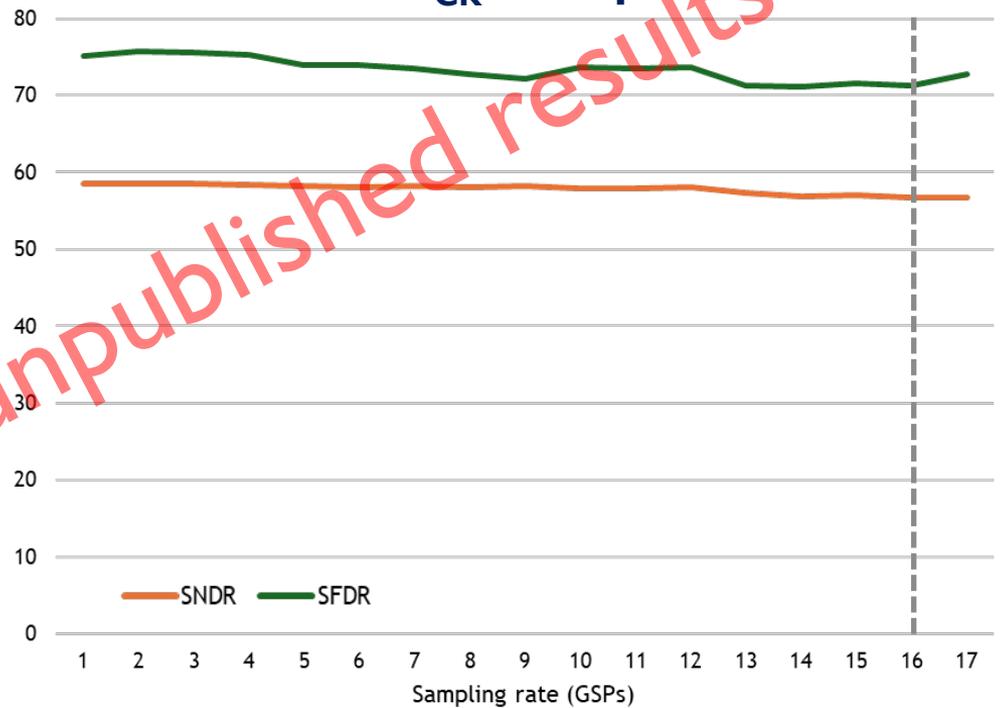


MEASURED PERFORMANCE – FREQUENCY SWEEPS

F_{IN} Sweep



F_{CK} Sweep



- ENOB > 8.7-b & SFDR > 63-dB across full BW

COMPARISON w/ SotA (≥ 10 GS/s > 7 ENOB)

Presented results

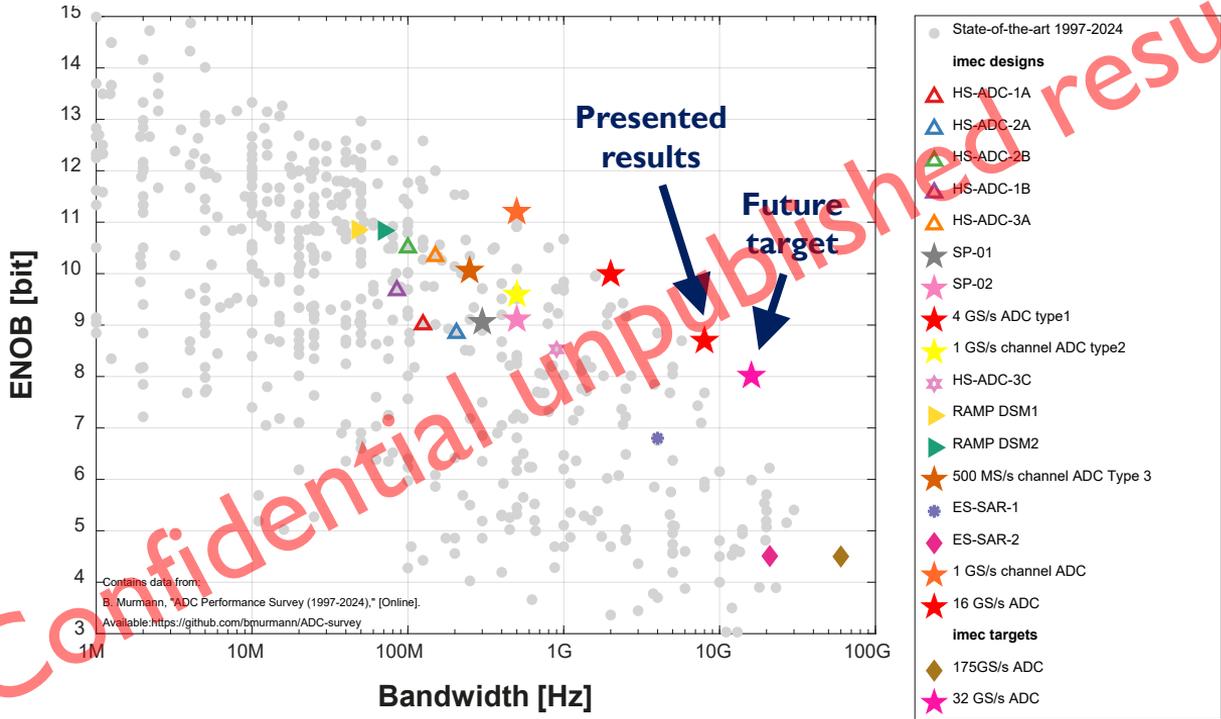
Future targets

	Imec ADC 2024 HSADC6	S. Kumar ISSCC'23 Socionext	K. Moon VLSI'22 Samsung	A. Ali ISSCC'20 ADI	S. Devarajan JSSC'17 ADI	Y. Cao ISSCC'24 Univ. Macau	Imec ADC 2026 Targets
Architecture	Pipelined 4x4 Hier. Interl.	Pipelined 8x10 H. Interl.	Pipelined 16x Dir. Interl.	Pipelined 1x8 Hier. Interl.	Pipelined 8x Dir. Interl.	Pipelined 4x Dir. Interl.	Pipelined MxN Hier. Interl.
Sampling rate [GS/s]	16.5	24	10	18	10	12	32
Bandwidth [GHz]	5	7.2	5	18	4	n.a.	> 20
Number of channels	16	80	16	8	8	4	< 12
Technology [nm]	16	7	5	16	28	28	3
Resolution [bit]	13	12	12	12	12	12	11
ENOB LF input [bit]	9.1	--	8*	8.3	9.4*	9.5	8.5
ENOB HF input [bit]	8.7	7.4	7.7	7.7	8.8	8.7	8.0
SNDR LF input [dB]	57	--	50*	52	58.5*	59.5*	53
SNDR HF input [dB]	53	46.5	48	48	55	54	50
SFDR HF [dB]	63	61 / 76#	61	54	64	66	70
Power [mW]	620	750	625	1300	2900	180	300
NSD [dBfs/Hz]	157	-147.5	n.a.	-157	-157	n.a.	153
FoM Walden [fj/c.s.]	91	181.0	305	351.9	631	36.2	29
FoM Schreier [dB]	153.3	148.5	147	146.4	147	159.3	158
Area [mm ²]	1	0.9	2.1	2.6	20.2	0.24	< 1

*estimated from the figure * buffer supply exists # with off-chip linearization

COMPARISON w/ SotA – RESOLUTION vs. SPEED

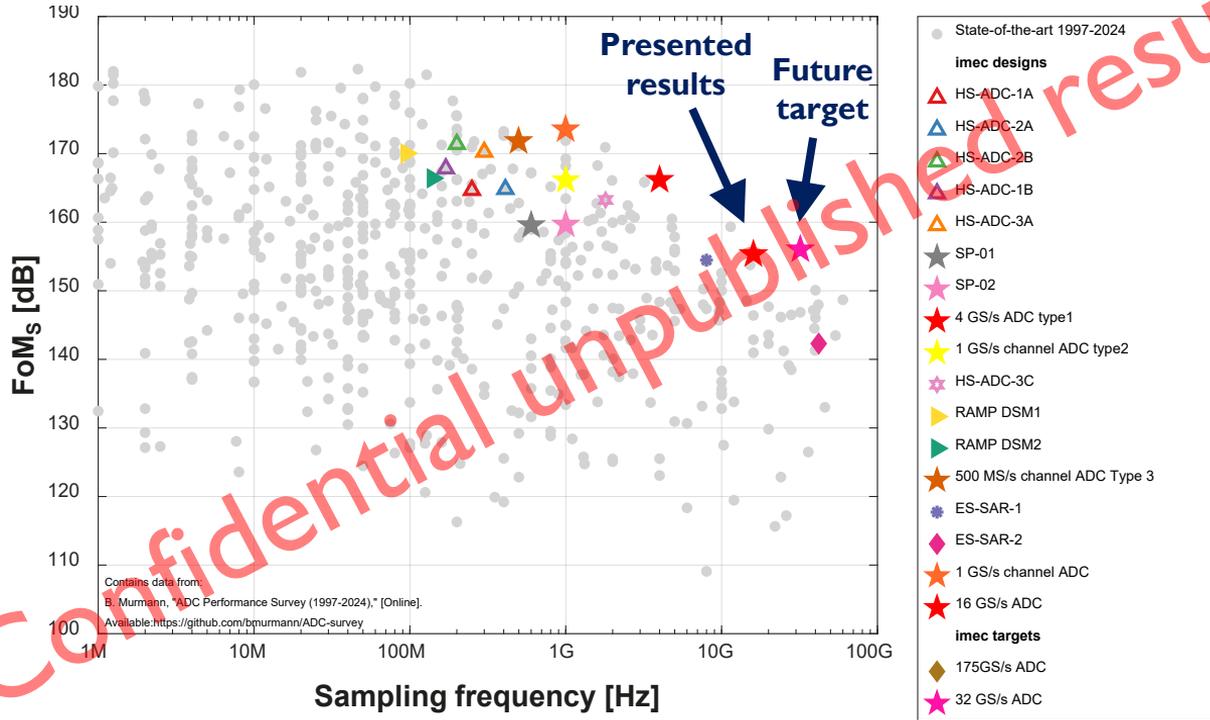
ISSCC/VLSI 1997-2024^[1]



Pushing the state-of-the-art in performance

COMPARISON w/ SotA – POWER EFFICIENCY vs. SPEED

ISSCC/VLSI 1997-2024^[1]



- Pushing the state-of-the-art in power efficiency

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CONCLUSIONS

- RF-sampling ADCs @ the core of key present & future applications
 - Important technical challenges for achieving ever-increasing performance targets
 - Make use of unconventional circuits & deep-nanoscale nodes
- Key technologies enabling high-performance, power-efficient RF-sampling ADCs
 - High-performance & power-efficient channel → ring amplification + asynchronous timing
 - SNDR-preserving hierarchical interleaving → split-cap sampling + active clear & rebuffering
 - High-linearity, wideband front-end buffer → varactor-based nonlinear-capacitance compensation
- No rad-hard counterparts exist for any of the presented techniques!
 - How do these circuits & nodes perform in space environments?
 - Can traditional hardening be applied without killing performance?
 - ...“run, but you can't hide”!
- Your turn for some awesome innovations!





THANK YOU FOR YOUR ATTENTION!

AMICSA 2025 – Lisbon, June 16th – 18th



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